

# 具有1.8V 逻辑电平的 TMUX1574 低电容、2:1 (SPDT) 4 通道 断电保护开关

## 1 特性

- 宽电源电压范围：1.5V 至 5.5V
- 低导通电容：7.5pF
- 低导通电阻：2Ω
- 高带宽：2GHz
- 工作温度范围：-40°C 至 +125°C
- 兼容 1.8V 逻辑电平
- 支持超出电源电压范围的输入电压
- 逻辑引脚上的集成下拉电阻器
- 双向信号路径
- 失效防护逻辑
- 高达 3.6V 信号的关断保护
  - 引脚排布与 SN74CBTLV3257 兼容

## 2 应用

- 服务器
- 数据中心交换机和路由器
- 无线基础设施
- PC 和笔记本电脑
- 楼宇自动化
- 电网基础设施
- 电子销售点 (ePOS)
- 电器
- 闪存存储器共享
- JTAG 多路复用
- SPI 多路复用

## 3 说明

TMUX1574 是一款互补金属氧化物半导体 (CMOS) 开关。TMUX1574 提供具有 4 个通道的 2:1 SPDT 开关配置。1.5V 至 5.5V 的宽运行电源电压范围使其可用于从服务器和通信设备到工业应用的各种应用理想之选。该器件可在源极 (SxA, SxB) 和漏极 (Dx) 引脚上支持双向模拟和数字信号，并且可以传递高于电源的信号（高达  $V_{DD} \times 2$ ），最大输入/输出电压为 5.5V。

TMUX1574 的信号路径上高达 3.6V 的关断保护可在移除电源电压 ( $V_{DD} = 0V$ ) 时提供隔离。如果没有该保护功能，开关可通过内部 ESD 二极管为电源轨进行反向供电，从而对系统造成潜在损坏。

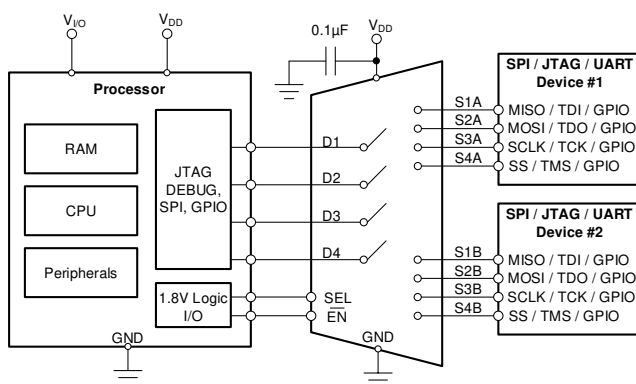
**失效防护逻辑** 电路允许在施加电源引脚上的电压之前，先施加逻辑控制引脚上的电压，从而保护器件免受潜在的损害。所有控制输入都具有兼容 1.8V 逻辑电平的阈值，当器件在有效电源电压范围内运行时，这些阈值可确保 TTL 和 CMOS 逻辑兼容性。逻辑引脚上带有集成下拉电阻 无需外部组件，可减少系统尺寸与成本。

器件信息(1)

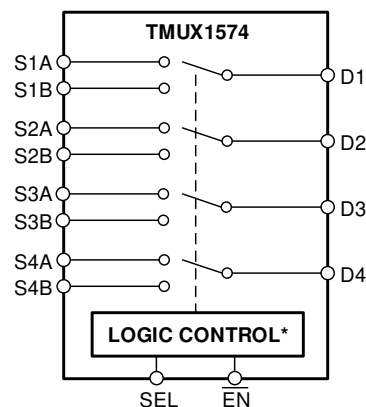
器件型号	封装	封装尺寸 (标称值)
TMUX1574	TSSOP (16)	5.00mm x 4.40mm
	UQFN (16)	2.60mm x 1.80mm
	SOT-23-THIN (16)	4.20mm x 2.00mm

(1) 如需了解所有可用封装，请参阅数据表末尾的封装选项附录。

应用示例



方框图



\*Internal 6MΩ Pull-Down on Logic Pins



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## 4 修订历史记录

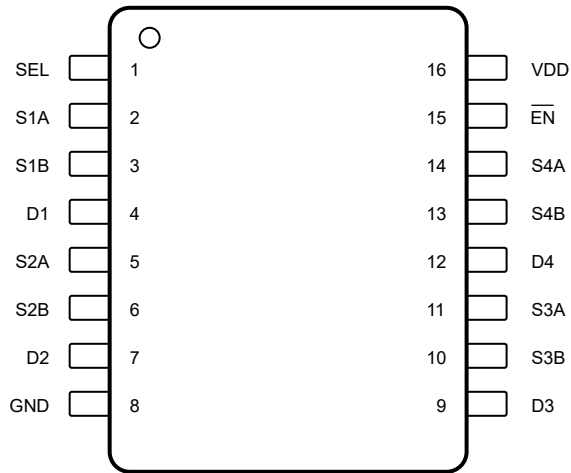
注：之前版本的页码可能与当前版本有所不同。

Changes from Revision A (December 2018) to Revision B	Page
• 向数据表添加了 SOT-23-THIN (DYY) 封装 .....	1
• Added thermal information for DYY package .....	5

Changes from Original (October 2018) to Revision A	Page
• 将文档状态从预告信息 更改为生产 数据 .....	1

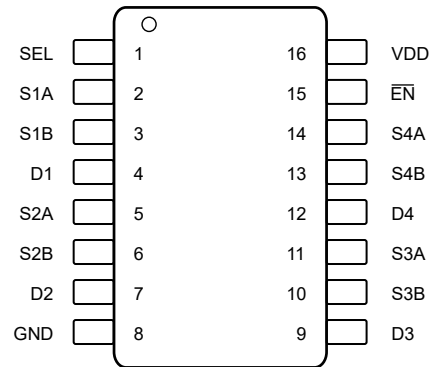
## 5 Pin Configuration and Functions

**PW Package**  
16-Pin TSSOP  
Top View

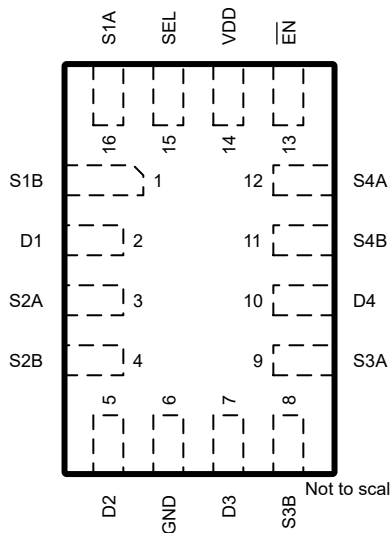


Not to scale

**DYY Package**  
16-Pin SOT-23-THIN  
Top View



**RSV Package**  
16-Pin UQFN  
Top View



Not to scale

### Pin Functions

PIN			TYPE <sup>(1)</sup>	DESCRIPTION <sup>(2)</sup>
NAME	TSSOP / SOT-23-THIN	UQFN		
SEL	1	15	I	Select pin: controls state of switches according to <a href="#">表 1</a> . Internal 6 MΩ pull-down to GND.
S1A	2	16	I/O	Source pin 1A. Can be an input or output.
S1B	3	1	I/O	Source pin 1B. Can be an input or output.
D1	4	2	I/O	Drain pin 1. Can be an input or output.
S2A	5	3	I/O	Source pin 2A. Can be an input or output.
S2B	6	4	I/O	Source pin 2B. Can be an input or output.
D2	7	5	I/O	Drain pin 2. Can be an input or output.
GND	8	6	P	Ground (0 V) reference
D3	9	7	I/O	Drain pin 3. Can be an input or output.
S3B	10	8	I/O	Source pin 3B. Can be an input or output.
S3A	11	9	I/O	Source pin 3A. Can be an input or output.
D4	12	10	I/O	Drain pin 4. Can be an input or output.
S4B	13	11	I/O	Source pin 4B. Can be an input or output.
S4A	14	12	I/O	Source pin 4A. Can be an input or output.
$\overline{\text{EN}}$	15	13	I	Active low enable: When this pin is high, all switches are turned off. When this pin is low, SEL pin controls the signal path selection. Internal 6 MΩ pull-down to GND.
VDD	16	14	P	Positive power supply. This pin is the most positive power-supply potential. For reliable operation, connect a decoupling capacitor ranging from 0.1 μF to 10 μF between V <sub>DD</sub> and GND.

(1) I = input, O = output, I/O = input and output, P = power

(2) Refer to [Device Functional Modes](#) for what to do with unused pins.

## 6 Specifications

### 6.1 Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted)<sup>(1)(2)(3)</sup>

		MIN	MAX	UNIT
$V_{DD}$	Supply voltage	-0.5	6	V
$V_{SEL}$ or $V_{EN}$	Logic control input pin voltage (SEL or $\overline{EN}$ )	-0.5	6	V
$I_{SEL}$ or $I_{EN}$	Logic control input pin current (SEL or $\overline{EN}$ )	-30	30	mA
$V_S$ or $V_D$	Source or drain pin voltage	-0.5	6	V
$I_S$ or $I_D$ (CONT)	Source and drain pin continuous current: (SxA, SxB, Dx)	-25	25	mA
$T_{stg}$	Storage temperature	-65	150	°C
$T_J$	Junction temperature		150	°C

- (1) Stresses beyond those listed under *Absolute Maximum Ratings* may cause permanent damage to the device. These are stress ratings only, which do not imply functional operation of the device at these or any other conditions beyond those indicated under *Recommended Operating Conditions*. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.
- (2) The algebraic convention, whereby the most negative value is a minimum and the most positive value is a maximum.
- (3) All voltages are with respect to ground, unless otherwise specified.

### 6.2 ESD Ratings

			VALUE	UNIT
$V_{(ESD)}$	Electrostatic discharge	Human body model (HBM), per ANSI/ESDA/JEDEC JS-001 <sup>(1)</sup>	±2000	V
		Charged-device model (CDM), per JEDEC specification JESD22-C101 <sup>(2)</sup>	±750	

- (1) JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process.
- (2) JEDEC document JEP157 states that 250-V CDM allows safe manufacturing with a standard ESD control process.

### 6.3 Recommended Operating Conditions

		MIN	MAX	UNIT
$V_{DD}$	Supply voltage	1.5	5.5	V
$V_S$ or $V_D$	Signal path input/output voltage (source or drain pin), $V_{DD} \geq 1.5$ V <sup>(1)</sup>	0	$V_{DD} \times 2$	V
$V_{S\_off}$ or $V_{D\_off}$	Signal path input/output voltage (source or drain pin), $V_{DD} < 1.5$ V <sup>(2)</sup>	0	3.6	V
$V_{SEL}$ or $V_{EN}$	Logic control input voltage ( $\overline{EN}$ , SEL)	0	5.5	V
$T_A$	Ambient temperature	-40	125	°C

- (1) Device input/output can operate up to  $V_{DD} \times 2$ , with a maximum input/output voltage of 5.5 V.
- (2)  $V_{S\_off}$  and  $V_{D\_off}$  refers to the voltage at the source or drain pins when supply is less than 1.5 V.

### 6.4 Thermal Information

THERMAL METRIC <sup>(1)</sup>		DEVICE	DEVICE	DEVICE	UNIT
		PW (TSSOP)	DYY (SOT-23)	RSV (UQFN)	
		16 PINS	16 PINS	16 PINS	
$R_{\theta JA}$	Junction-to-ambient thermal resistance	117.4	123.0	129.2	°C/W
$R_{\theta JC(top)}$	Junction-to-case (top) thermal resistance	47.9	70.5	69.7	°C/W
$R_{\theta JB}$	Junction-to-board thermal resistance	63.7	50.4	58.7	°C/W
$\Psi_{JT}$	Junction-to-top characterization parameter	6.9	5.0	3.6	°C/W
$\Psi_{JB}$	Junction-to-board characterization parameter	63.1	50.3	56.8	°C/W
$R_{\theta JC(bot)}$	Junction-to-case (bottom) thermal resistance	N/A	N/A	N/A	°C/W

- (1) For more information about traditional and new thermal metrics, see the [Semiconductor and IC Package Thermal Metrics](#) application report.

## 6.5 Electrical Characteristics

 $V_{DD} = 1.5\text{ V to }5.5\text{ V}$ ,  $GND = 0\text{ V}$ ,  $T_A = -40^\circ\text{C to }+125^\circ\text{C}$ 

 Typical values are at  $V_{DD} = 3.3\text{ V}$ ,  $T_A = 25^\circ\text{C}$ , (unless otherwise noted)

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
<b>POWER SUPPLY</b>						
$V_{DD}$	Power supply voltage		1.5		5.5	V
$I_{DD}$	Active supply current	$V_{SEL} = 0\text{ V, }1.4\text{ V or }V_{DD}$ $V_S = 0\text{ V to }5.5\text{ V}$		40	68	$\mu\text{A}$
$I_{DD\_STANDBY}$	Supply current when disabled	$V_{EN} = 1.4\text{ V or }V_{DD}$ $V_S = 0\text{ V to }5.5\text{ V}$		7.5	15	$\mu\text{A}$
<b>DC CHARACTERISTICS</b>						
$R_{ON}$	On-resistance	$V_S = 0\text{ V to }V_{DD} \cdot 2$ $V_{S(max)} = 5.5\text{ V}$ $I_{SD} = 8\text{ mA}$ Refer to <a href="#">ON-State Resistance Figure</a>		2	4.5	$\Omega$
$\Delta R_{ON}$	On-resistance match between channels	$V_S = V_{DD}$ $I_{SD} = 8\text{ mA}$ Refer to <a href="#">ON-State Resistance Figure</a>		0.07	0.28	$\Omega$
$R_{ON(FLAT)}$	On-resistance flatness	$V_S = 0\text{ V to }V_{DD}$ $I_{SD} = 8\text{ mA}$ Refer to <a href="#">ON-State Resistance Figure</a>		1	1.8	$\Omega$
$I_{POFF}$	Powered-off I/O pin leakage current	$V_{DD} = 0\text{ V}$ $V_S = 0\text{ V to }3\text{ V}$ $V_D = 0\text{ V}$ $T_A = 25^\circ\text{C}$ Refer to <a href="#">I<sub>po</sub>ff Leakage Figure</a>	-10	0.01	10	nA
$I_{POFF}$	Powered-off I/O pin leakage current	$V_{DD} = 0\text{ V}$ $V_S = 0\text{ V to }3.6\text{ V}$ $V_D = 0\text{ V}$ Refer to <a href="#">I<sub>po</sub>ff Leakage Figure</a>	-2	0.01	2	$\mu\text{A}$
$I_{S(OFF)}$ $I_{D(OFF)}$	OFF leakage current	Switch Off $V_D = 0.8 \cdot V_{DD} / 0.2 \cdot V_{DD}$ $V_S = 0.2 \cdot V_{DD} / 0.8 \cdot V_{DD}$ Refer to <a href="#">Off Leakage Figure</a>	-100	0.03	100	nA
$I_{D(ON)}$ $I_{S(ON)}$	ON leakage current	Switch On $V_D = 0.8 \cdot V_{DD} / 0.2 \cdot V_{DD}$ , S pins floating or $V_S = 0.8 \cdot V_{DD} / 0.2 \cdot V_{DD}$ , D pins floating Refer to <a href="#">On Leakage Figure</a>	-50	0.01	50	nA
<b>LOGIC INPUTS</b>						
$V_{IH}$	Input logic high		1.2		5.5	V
$V_{IL}$	Input logic low		0		0.45	V
$I_{IH}$	Input high leakage current	$V_{SEL} = 1.8\text{ V, }V_{DD}$		1	$\pm 2$	$\mu\text{A}$
$I_{IL}$	Input low leakage current	$V_{SEL} = 0\text{ V}$		0.2	$\pm 2$	$\mu\text{A}$
$R_{PD}$	Internal pull-down resistor on logic pins			6		M $\Omega$
$C_1$	Logic input capacitance	$V_{SEL} = 0\text{ V, }1.8\text{ V or }V_{DD}$ $f = 1\text{ MHz}$		3		pF

## 6.6 Dynamic Characteristics

 $V_{DD} = 1.5\text{ V to }5.5\text{ V}$ ,  $GND = 0\text{ V}$ ,  $T_A = -40^\circ\text{C to }+125^\circ\text{C}$ 

 Typical values are at  $V_{DD} = 3.3\text{ V}$ ,  $T_A = 25^\circ\text{C}$ , (unless otherwise noted)

PARAMETER		TEST CONDITIONS		MIN	TYP	MAX	UNIT
$C_{OFF}$	Source and drain off capacitance	$V_S = 2.5\text{ V}$ $V_{SEL} = 0\text{ V}$ $f = 1\text{ MHz}$ Refer to <a href="#">Capacitance Figure</a>	Switch OFF		3.5	6	pF
$C_{ON}$	Source and drain on capacitance	$V_S = 2.5\text{ V}$ $V_{SEL} = 0\text{ V}$ $f = 1\text{ MHz}$ Refer to <a href="#">Capacitance Figure</a>	Switch ON		7.5	12	pF
$Q_C$	Charge Injection	$V_S = V_{DD}/2$ $R_S = 0\ \Omega$ , $C_L = 1\text{ nF}$ Refer to <a href="#">Charge Injection Figure</a>	Switch ON		3.5		pC
$O_{ISO}$	Off isolation	$R_L = 50\ \Omega$ $f = 100\text{ kHz}$ Refer to <a href="#">Off Isolation Figure</a>	Switch OFF		-90		dB
		$R_L = 50\ \Omega$ $f = 1\text{ MHz}$ Refer to <a href="#">Off Isolation Figure</a>	Switch OFF		-75		dB
$X_{TALK}$	Channel to Channel crosstalk	$R_L = 50\ \Omega$ $f = 100\text{ kHz}$ Refer to <a href="#">Crosstalk Figure</a>	Switch ON		-90		dB
BW	Bandwidth	$R_L = 50\ \Omega$ Refer to <a href="#">Bandwidth Figure</a>	Switch ON		2		GHz
$I_{LOSS}$	Insertion loss	$R_L = 50\ \Omega$ $f = 1\text{ MHz}$ Refer to <a href="#">Bandwidth Figure</a>	Switch ON		-0.12		dB

## 6.7 Timing Requirements

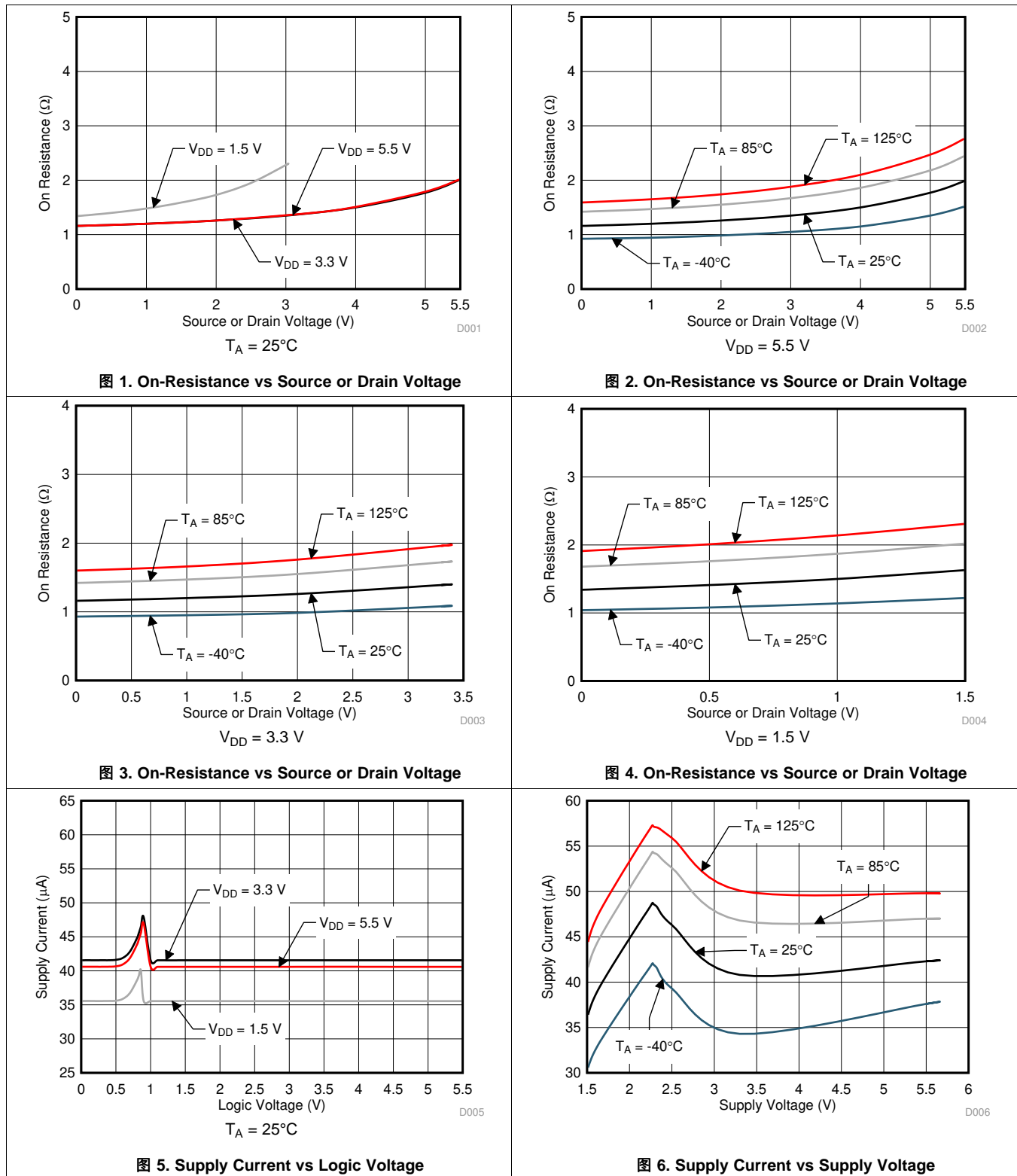
 $V_{DD} = 1.5\text{ V to }5.5\text{ V}$ ,  $GND = 0\text{ V}$ ,  $T_A = -40^\circ\text{C to }+125^\circ\text{C}$ 

 Typical values are at  $V_{DD} = 3.3\text{ V}$ ,  $T_A = 25^\circ\text{C}$ , (unless otherwise noted)

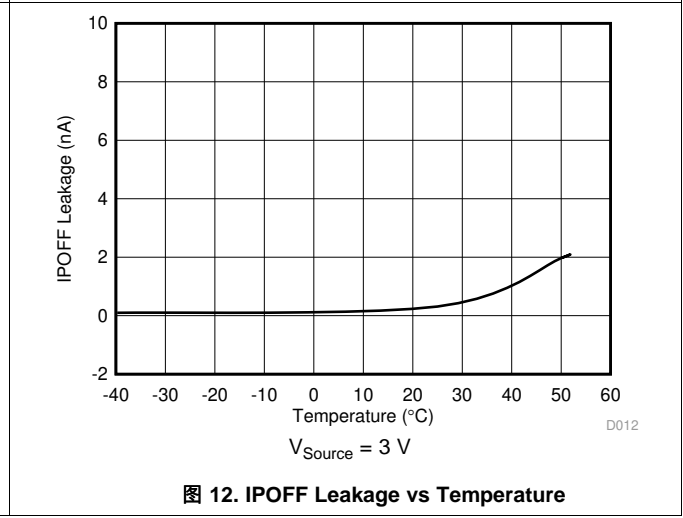
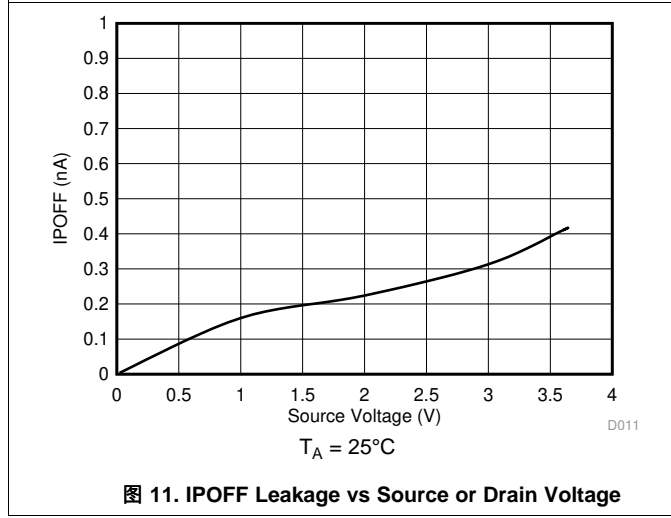
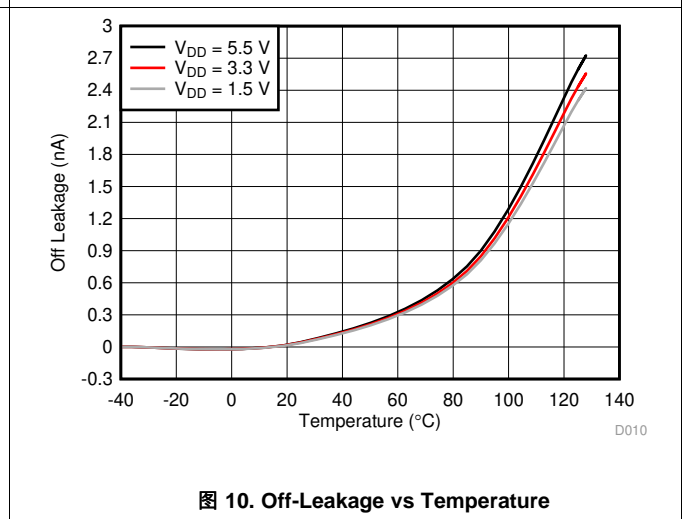
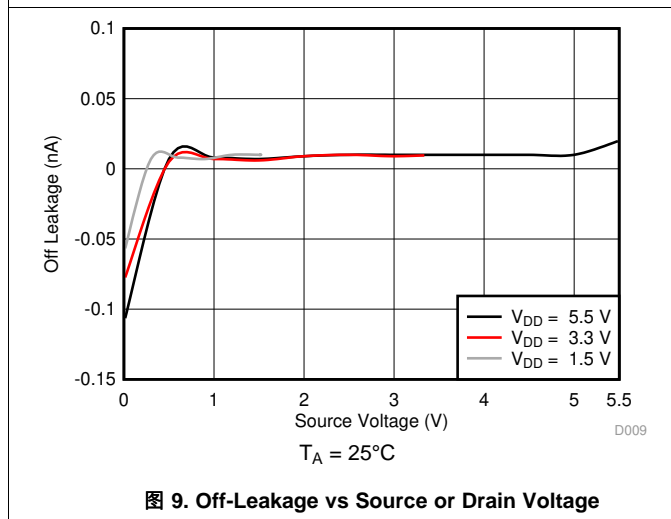
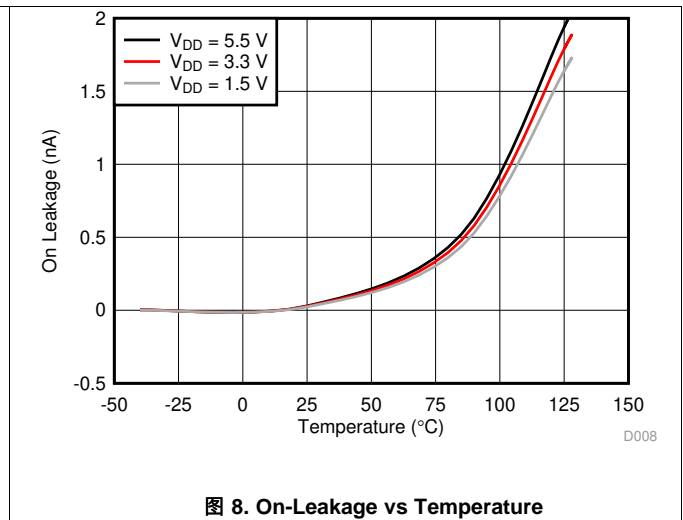
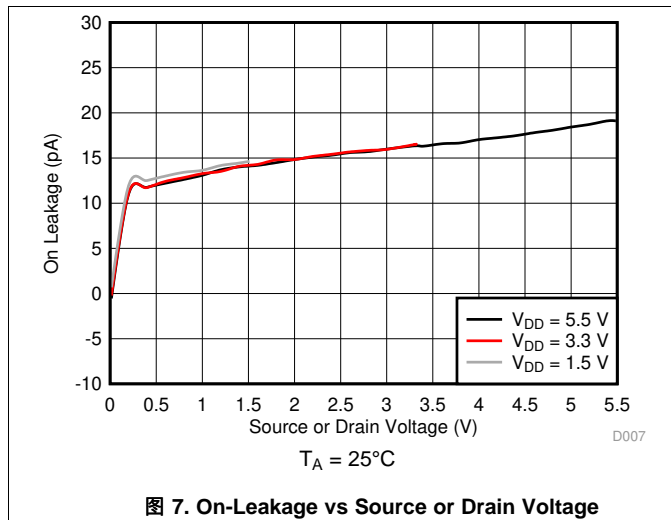
PARAMETER		TEST CONDITIONS	MIN	NOM	MAX	UNIT
$t_{\text{TRAN}}$	Transition time from control input	$V_{DD} = 2.5\text{ V to }5.5\text{ V}$ $V_S = V_{DD}$ $R_L = 200\ \Omega$ , $C_L = 15\text{ pF}$ Refer to <a href="#">Transition Timing Figure</a>		160	350	ns
$t_{\text{TRAN}}$	Transition time from control input	$V_{DD} < 2.5\text{ V}$ $V_S = V_{DD}$ $R_L = 200\ \Omega$ , $C_L = 15\text{ pF}$ Refer to <a href="#">Transition Timing Figure</a>		180	580	ns
$t_{\text{ON(EN)}}$	Device turn on time from enable pin	$V_S = V_{DD}$ $R_L = 200\ \Omega$ , $C_L = 15\text{ pF}$ Refer to <a href="#">Ton(EN) &amp; Toff(EN) Figure</a>		12	35	$\mu\text{s}$
$t_{\text{OFF(EN)}}$	Device turn off time from enable pin	$V_S = V_{DD}$ $R_L = 200\ \Omega$ , $C_L = 15\text{ pF}$ Refer to <a href="#">Ton(EN) &amp; Toff(EN) Figure</a>		50	95	ns
$t_{\text{ON(VDD)}}$	Device turn on time ( $V_{DD}$ to output)	$V_S = 3.6\text{ V}$ $V_{DD}$ rise time = $1\ \mu\text{s}$ $R_L = 200\ \Omega$ , $C_L = 15\text{ pF}$ Refer to <a href="#">Ton(vdd) &amp; Toff(vdd) Figure</a>		20	60	$\mu\text{s}$
$t_{\text{OFF(VDD)}}$	Device turn off time ( $V_{DD}$ to output)	$V_S = 3.6\text{ V}$ $V_{DD}$ fall time = $1\ \mu\text{s}$ $R_L = 200\ \Omega$ , $C_L = 15\text{ pF}$ Refer to <a href="#">Ton(vdd) &amp; Toff(vdd) Figure</a>		1.2	2.7	$\mu\text{s}$
$t_{\text{OPEN (BBM)}}$	Break before make time	$V_S = 1\text{ V}$ $R_L = 200\ \Omega$ , $C_L = 15\text{ pF}$ Refer to <a href="#">Topen(BBM) Figure</a>	0.5			ns
$t_{\text{SK(P)}}$	Inter - channel skew - QFN (RSV)	Refer to <a href="#">Tsk Figure</a>		5		ps
$t_{\text{SK(P)}}$	Inter - channel skew - DYY (SOT-23)	Refer to <a href="#">Tsk Figure</a>		10		ps
$t_{\text{SK(P)}}$	Inter - channel skew - TSSOP (PW)	Refer to <a href="#">Tsk Figure</a>		18		ps
$t_{\text{PD}}$	Propagation delay - QFN (RSV)	Refer to <a href="#">Tpd Figure</a>		50		ps
$t_{\text{PD}}$	Propagation delay - DYY (SOT-23)	Refer to <a href="#">Tpd Figure</a>		70		ps
$t_{\text{PD}}$	Propagation delay - TSSOP (PW)	Refer to <a href="#">Tpd Figure</a>		95		ps

### 6.8 Typical Characteristics

at  $T_A = 25^\circ\text{C}$ ,  $V_{DD} = 5\text{ V}$  (unless otherwise noted)



Typical Characteristics (接下页)



Typical Characteristics (接下页)

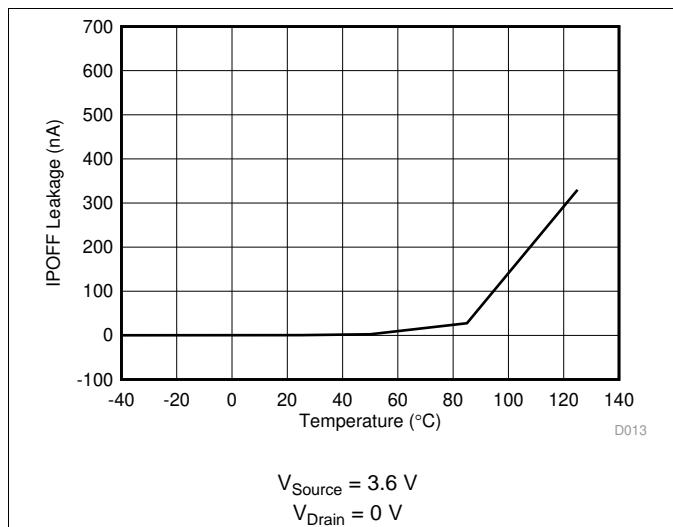


图 13. IPOFF Leakage vs Temperature

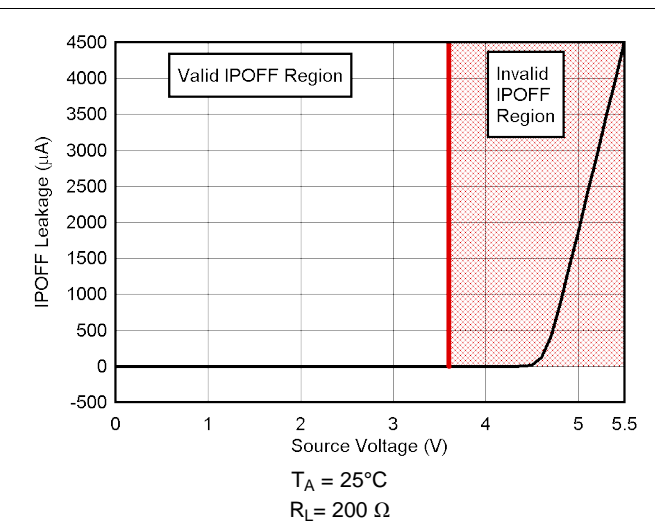


图 14. IPOFF Leakage vs Source or Drain Voltage

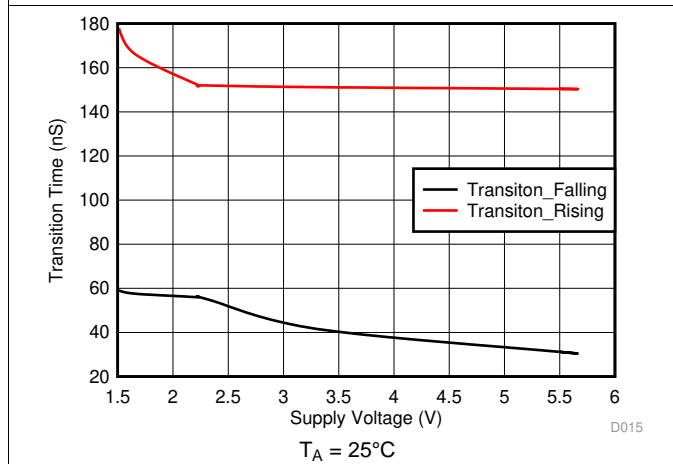


图 15. TTRANSITION vs Supply Voltage

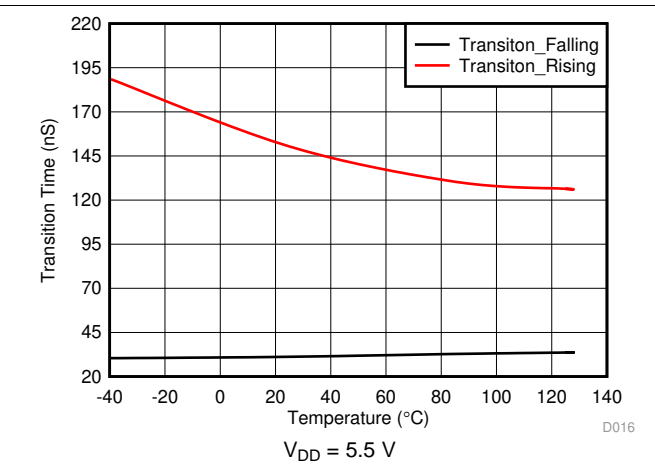


图 16. TTRANSITION vs Temperature

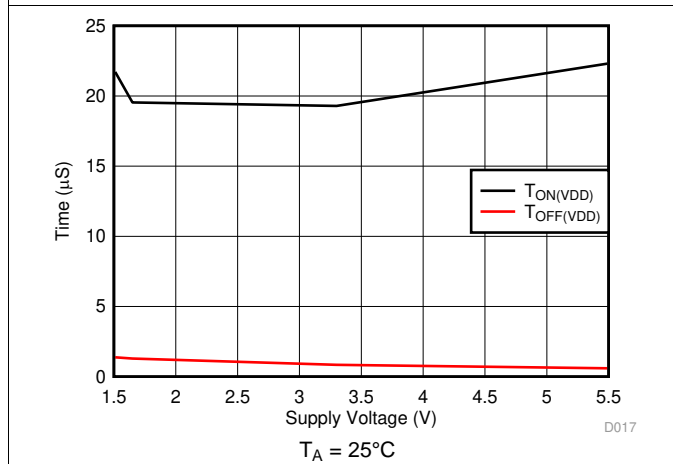


图 17. TON (VDD) and TOFF (VDD) vs Supply Voltage

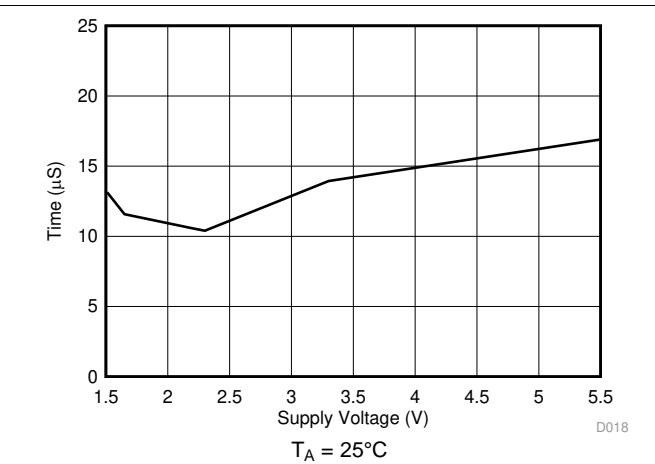


图 18. TON (EN) vs Supply Voltage

Typical Characteristics (接下页)

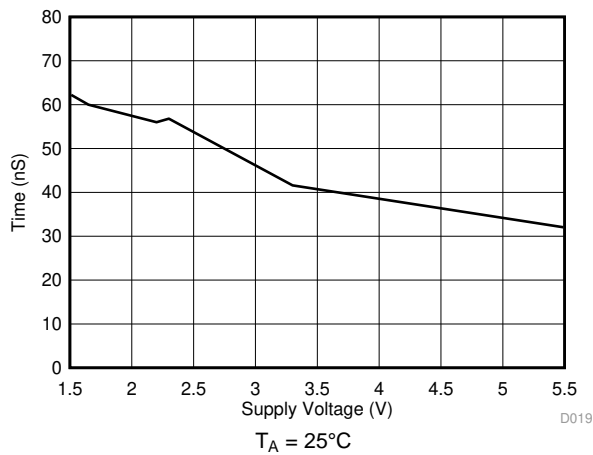


图 19. T<sub>OFF</sub> (EN) vs Supply Voltage

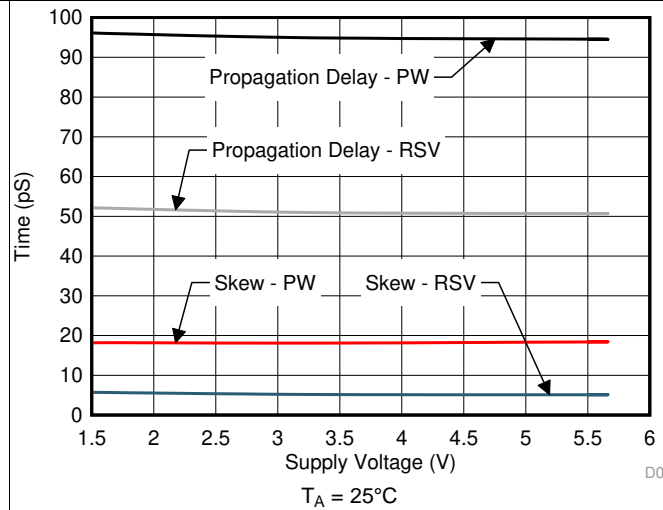


图 20. Skew and Propagation Delay vs Supply Voltage

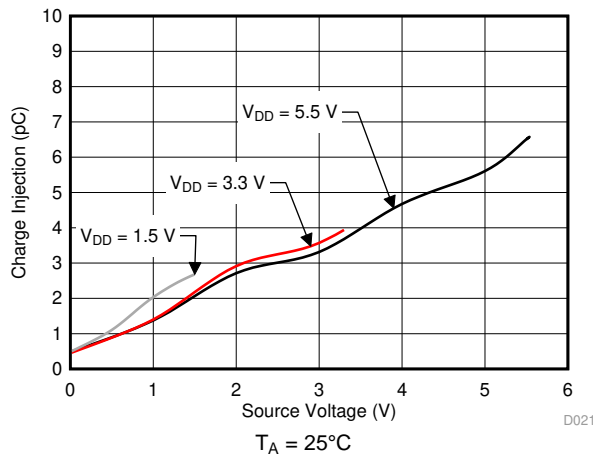


图 21. Charge Injection vs Source Voltage

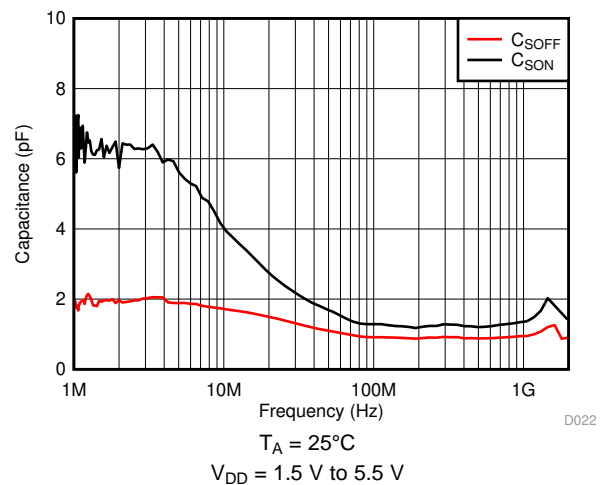


图 22. Capacitance vs Frequency

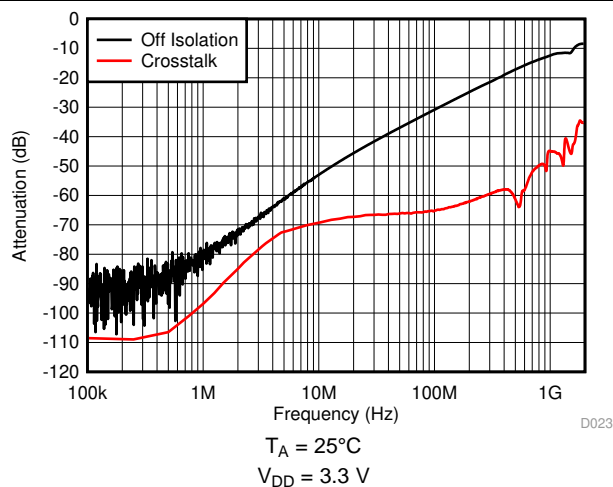


图 23. Off Isolation and Crosstalk vs Frequency

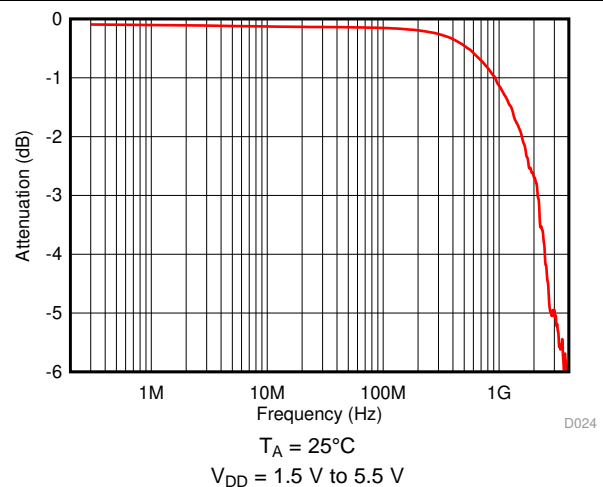
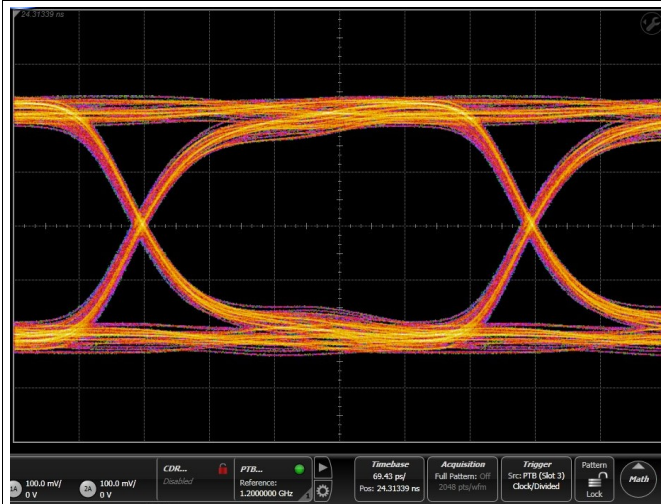


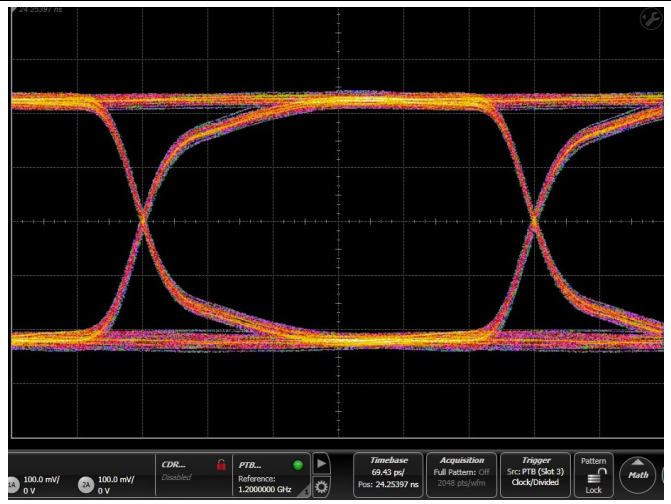
图 24. On-Response vs Frequency

### 6.8.1 Eye Diagrams



$T_A = 25^\circ\text{C}$   
Bias = 1.5 V  
50  $\Omega$  Termination

图 25. Eye Pattern: 2.4 Gbps



$T_A = 25^\circ\text{C}$   
Bias = 1.5 V  
50  $\Omega$  Termination

图 26. Eye Pattern: 2.4 Gbps Through Path

## 7 Parameter Measurement Information

### 7.1 On-Resistance

The on-resistance of a device is the ohmic resistance between the source (Sx) and drain (Dx) pins of the device. The on-resistance varies with input voltage and supply voltage. The symbol  $R_{ON}$  is used to denote on-resistance. The measurement setup used to measure  $R_{ON}$  is shown in Figure 27. Voltage (V) and current ( $I_{SD}$ ) are measured using this setup, and  $R_{ON}$  is computed as shown below with  $R_{ON} = V / I_{SD}$ :

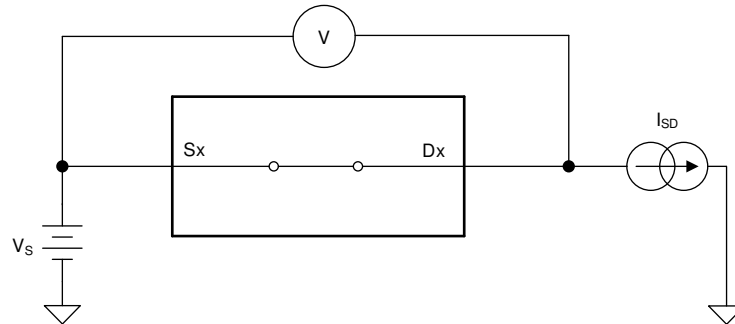


图 27. On-Resistance Measurement Setup

### 7.2 Off-Leakage Current

Source leakage current is defined as the leakage current flowing into or out of the source pin when the switch is off. This current is denoted by the symbol  $I_{S(OFF)}$ .

Drain leakage current is defined as the leakage current flowing into or out of the drain pin when the switch is off. This current is denoted by the symbol  $I_{D(OFF)}$ .

The setup used to measure both off-leakage currents is shown in Figure 28.

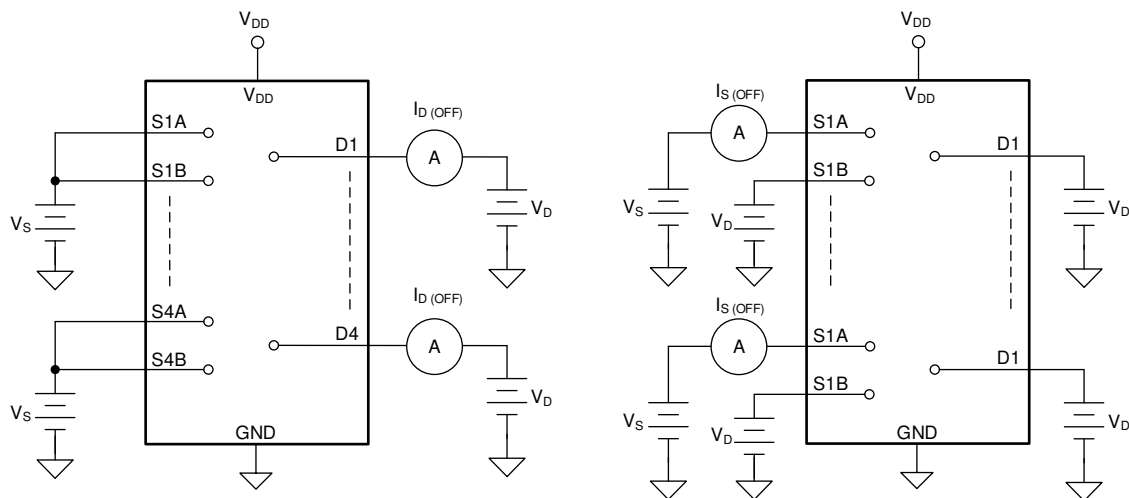


图 28. Off-Leakage Measurement Setup

### 7.3 On-Leakage Current

Source on-leakage current is defined as the leakage current flowing into or out of the source pin when the switch is on. This current is denoted by the symbol  $I_{S(ON)}$ .

Drain on-leakage current is defined as the leakage current flowing into or out of the drain pin when the switch is on. This current is denoted by the symbol  $I_{D(ON)}$ .

Either the source pin or drain pin is left floating during the measurement. 图 29 shows the circuit used for measuring the on-leakage current, denoted by  $I_{S(ON)}$  or  $I_{D(ON)}$ .

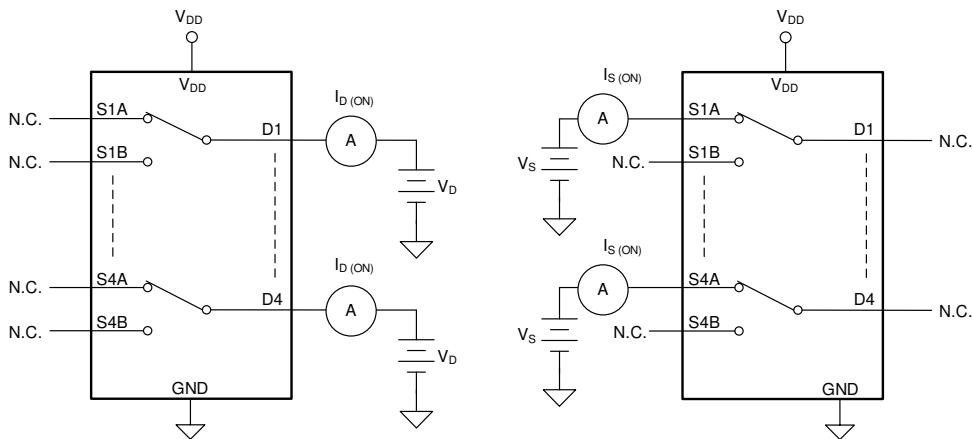


图 29. On-Leakage Measurement Setup

### 7.4 $I_{POFF}$ Leakage Current

$I_{POFF}$  leakage current is defined as the leakage current flowing into or out of the source pin when the device is powered off. This current is denoted by the symbol  $I_{POFF}$ .

The setup used to measure both  $I_{POFF}$  leakage current is shown in 图 30.

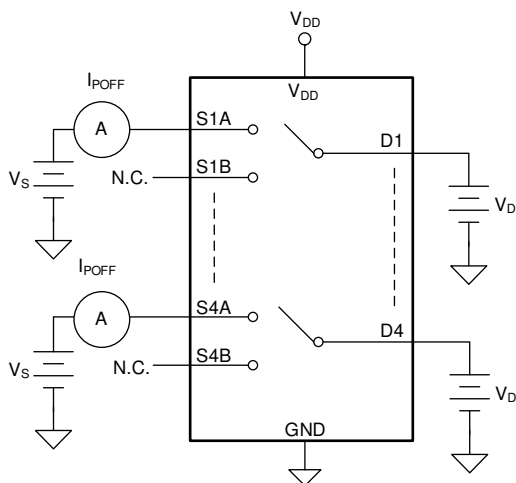
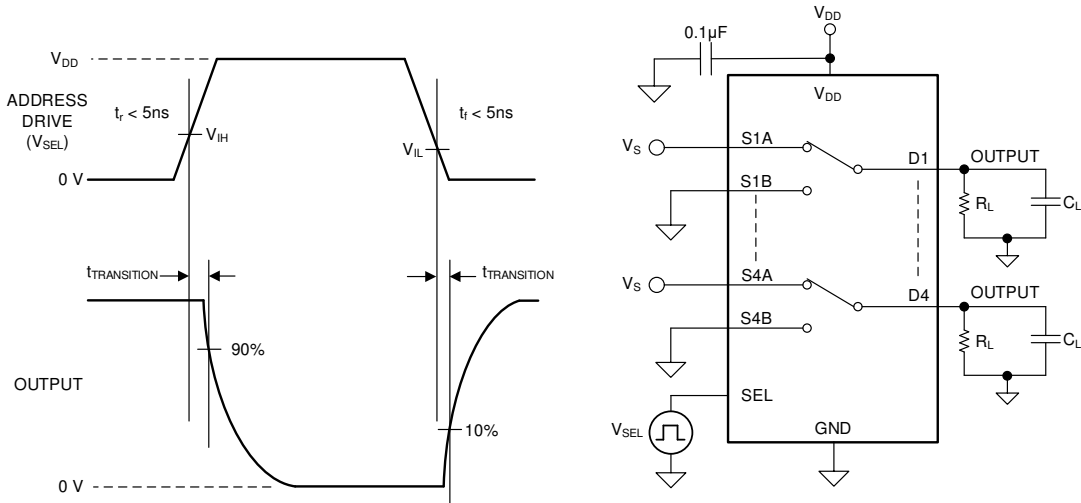


图 30.  $I_{POFF}$  Leakage Measurement Setup

### 7.5 Transition Time

Transition time is defined as the time taken by the output of the device to rise or fall 10% after the select signal has risen or fallen past the logic threshold. The 10% transition measurement is utilized to provide the timing of the device. The time constant from the load resistance and load capacitance can be added to the transition time to calculate system level timing.  shows the setup used to measure transition time, denoted by the symbol  $t_{\text{TRANSITION}}$ .

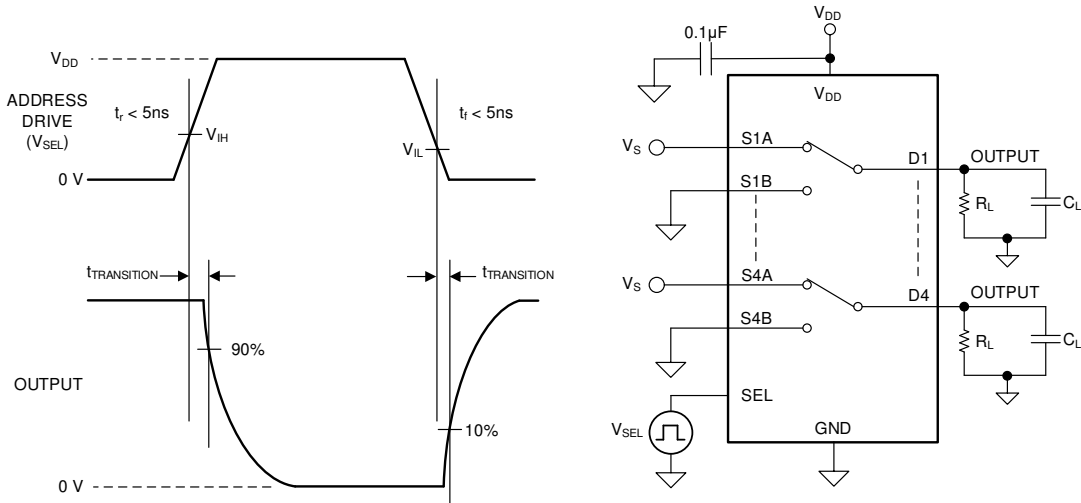
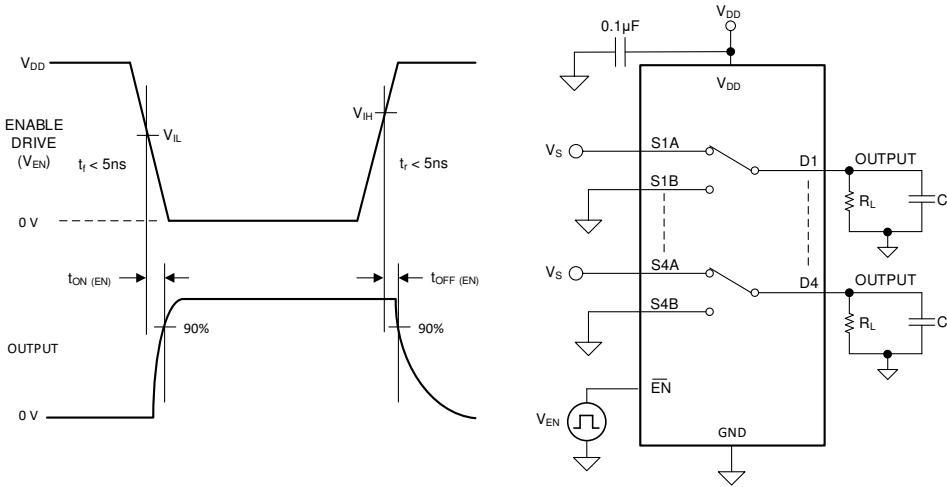
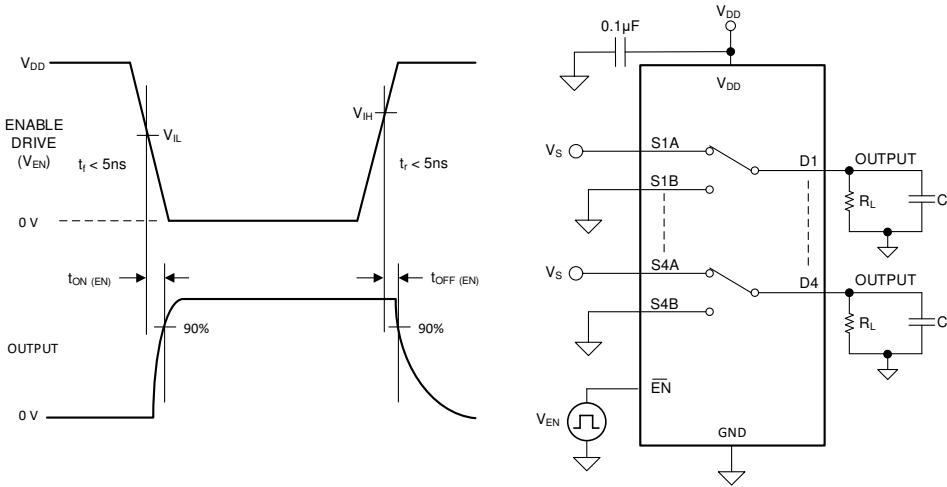


图 31. Transition-Time Measurement Setup

### 7.6 $t_{\text{ON (EN)}}$ and $t_{\text{OFF (EN)}}$ Time

The  $t_{\text{ON (EN)}}$  time is defined as the time taken by the output of the device to rise to 90% after the enable has fallen past the logic threshold. The 90% measurement is used to provide the timing of the device being enabled in the system.  shows the setup used to measure the enable time, denoted by the symbol  $t_{\text{ON (EN)}}$ .

The  $t_{\text{OFF (EN)}}$  time is defined as the time taken by the output of the device to fall to 90% after the enable has fallen past the logic threshold. The 90% measurement is used to provide the timing of the device being disabled in the system.  shows the setup used to measure enable time, denoted by the symbol  $t_{\text{OFF (EN)}}$ .

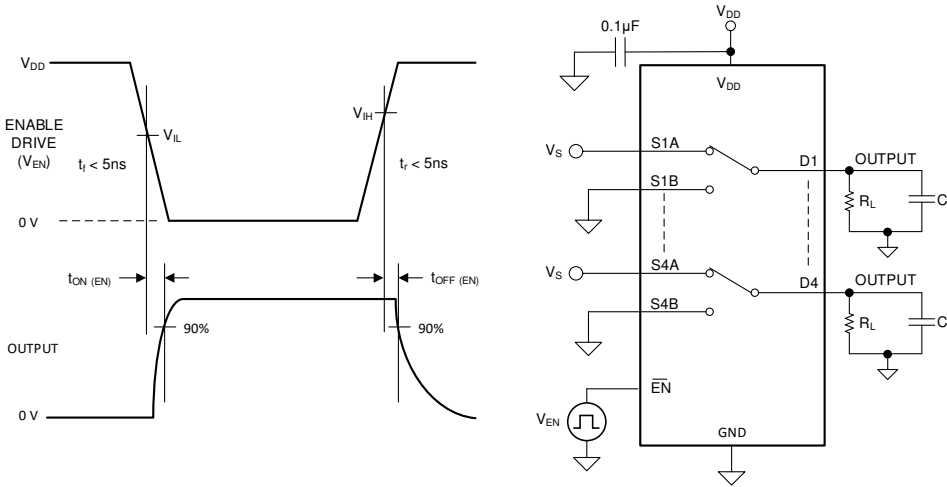


图 32.  $t_{\text{ON (EN)}}$  and  $t_{\text{OFF (EN)}}$  Time Measurement Setup

### 7.7 $t_{ON(VDD)}$ and $t_{OFF(VDD)}$ Time

The  $t_{ON(VDD)}$  time is defined as the time taken by the output of the device to rise to 90% after the supply has risen past the supply threshold. The 90% measurement is used to provide the timing of the device turning on in the system. 图 33 shows the setup used to measure turn on time, denoted by the symbol  $t_{ON(VDD)}$ .

the  $t_{OFF(VDD)}$  time is defined as the time taken by the output of the device to fall to 90% after the supply has fallen past the supply threshold. The 90% measurement is used to provide the timing of the device turning off in the system. 图 33 shows the setup used to measure turn off time, denoted by the symbol  $t_{OFF(VDD)}$ .

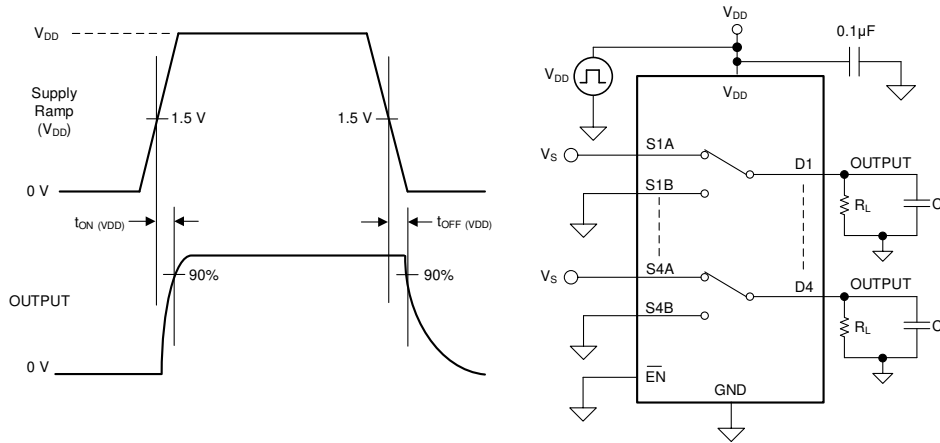


图 33.  $t_{ON(VDD)}$  and  $t_{OFF(VDD)}$  Time Measurement Setup

### 7.8 Break-Before-Make Delay

Break-before-make delay is a safety feature that prevents two inputs from connecting when the device is switching. The output first breaks from the on-state switch before making the connection with the next on-state switch. The time delay between the *break* and the *make* is known as break-before-make delay. 图 34 shows the setup used to measure break-before-make delay, denoted by the symbol  $t_{OPEN(BBM)}$ .

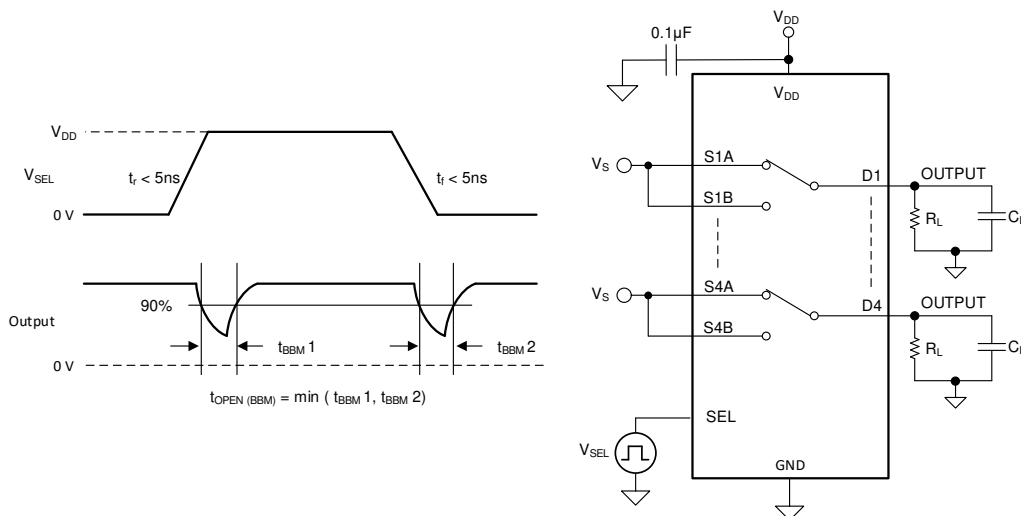


图 34. Break-Before-Make Delay Measurement Setup

## 7.9 Propagation Delay

Propagation delay is defined as the time taken by the output of the device to rise or fall 50% after the input signal has risen or fallen past the 50% threshold. 图 35 shows the setup used to measure propagation delay, denoted by the symbol  $t_{PD}$ .

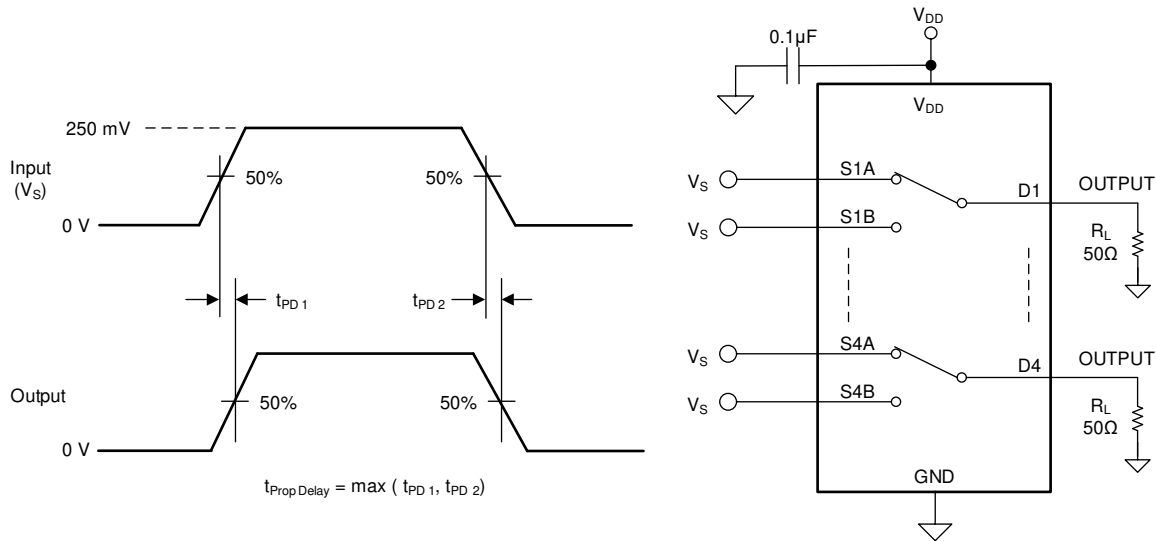


图 35. Propagation Delay Measurement Setup

## 7.10 Skew

Skew is defined as the difference between propagation delays of any two outputs of the same device. The skew measurement is taken from the output of one channel rising or falling past 50% to a second channel rising or falling past the 50% threshold when the input signals are switched at the same time. 图 36 shows the setup used to measure skew, denoted by the symbol  $t_{SK}$ .

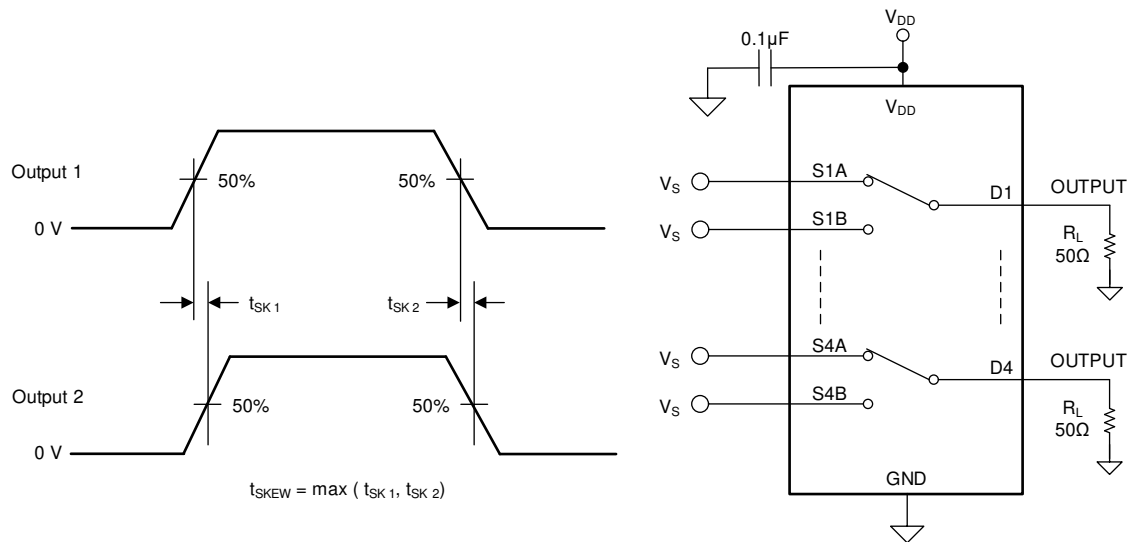


图 36. Skew Measurement Setup

### 7.11 Charge Injection

The amount of charge injected into the source or drain of the device during the falling or rising edge of the gate signal is known as charge injection, and is denoted by the symbol  $Q_C$ . 图 37 shows the setup used to measure charge injection from source (Sx) to drain (Dx).

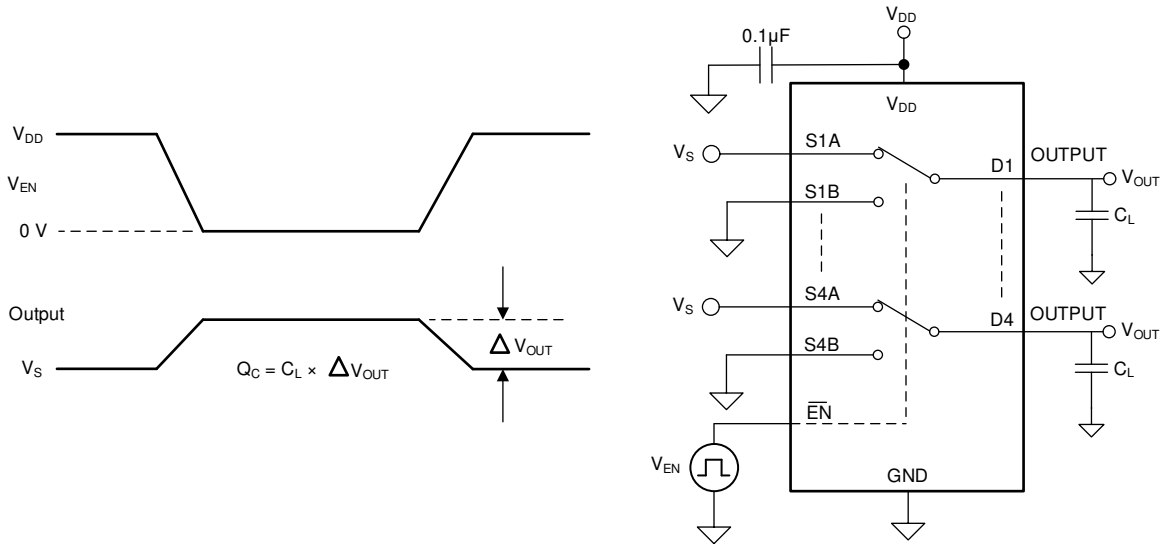


图 37. Charge-Injection Measurement Setup

### 7.12 Capacitance

The parasitic capacitance of the device is captured at the source (Sx), drain (Dx), and select (SELx) pins. The capacitance is measured in both the on and off state and is denoted by the symbol  $C_{ON}$  and  $C_{OFF}$ . 图 38 shows the setup used to measure capacitance.

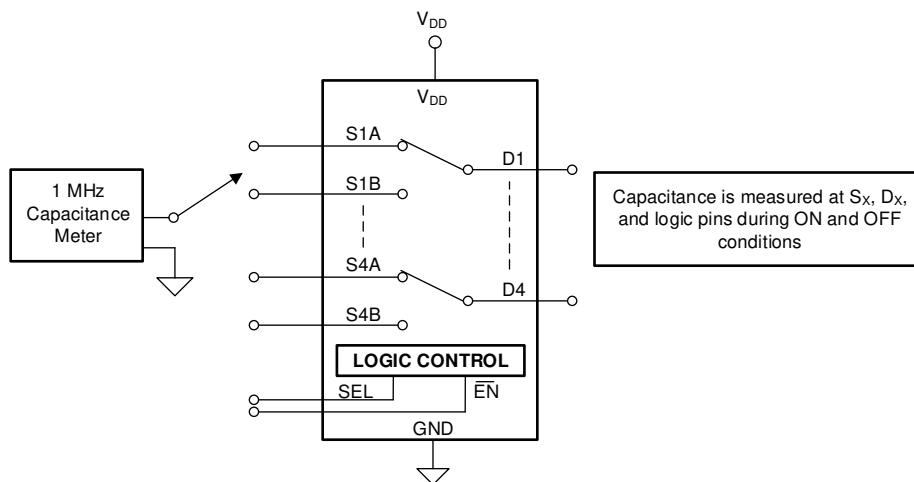


图 38. Capacitance Measurement Setup

### 7.13 Off Isolation

Off isolation is defined as the ratio of the signal at the drain pin (Dx) of the device when a signal is applied to the source pin (Sx) of an off-channel. The characteristic impedance,  $Z_0$ , for the measurement is  $50\ \Omega$ . shows the setup used to measure off isolation. Use off isolation equation to compute off isolation.

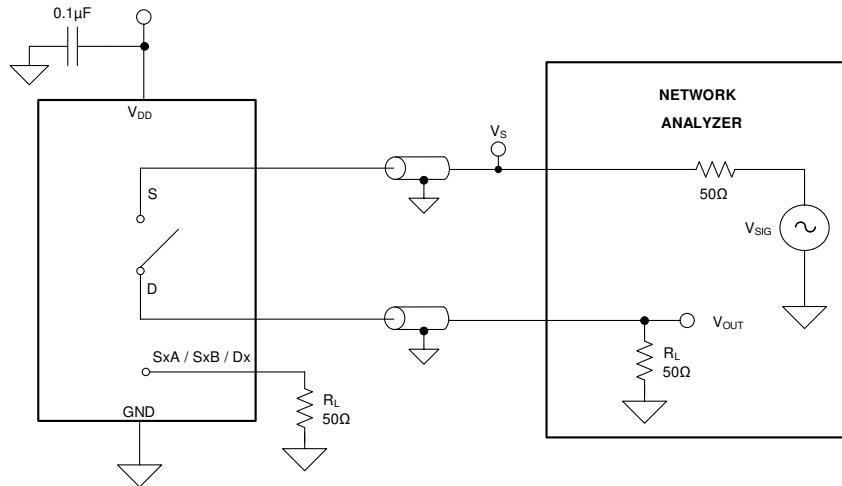


图 39. Off Isolation Measurement Setup

$$\text{Off Isolation} = 20 \cdot \text{Log} \left( \frac{V_{\text{OUT}}}{V_{\text{S}}} \right) \tag{1}$$

### 7.14 Channel-to-Channel Crosstalk

Crosstalk is defined as the ratio of the signal at the drain pin (Dx) of a different channel, when a signal is applied at the source pin (Sx) of an on-channel. The characteristic impedance,  $Z_0$ , for the measurement is  $50\ \Omega$ . shows the setup used to measure, and the equation used to compute crosstalk.

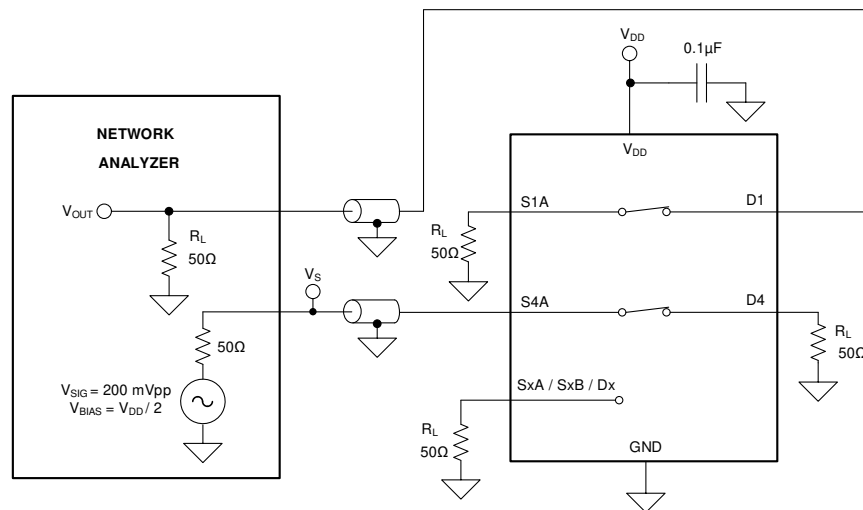


图 40. Channel-to-Channel Crosstalk Measurement Setup

$$\text{Channel-to-Channel Crosstalk} = 20 \cdot \text{Log} \left( \frac{V_{\text{OUT}}}{V_{\text{S}}} \right) \tag{2}$$

## 7.15 Bandwidth

Bandwidth is defined as the range of frequencies that are attenuated by less than 3 dB when the input is applied to the source pin (Sx) of an on-channel, and the output is measured at the drain pin (Dx) of the device. The characteristic impedance,  $Z_0$ , for the measurement is 50  $\Omega$ . 图 41 shows the setup used to measure bandwidth.

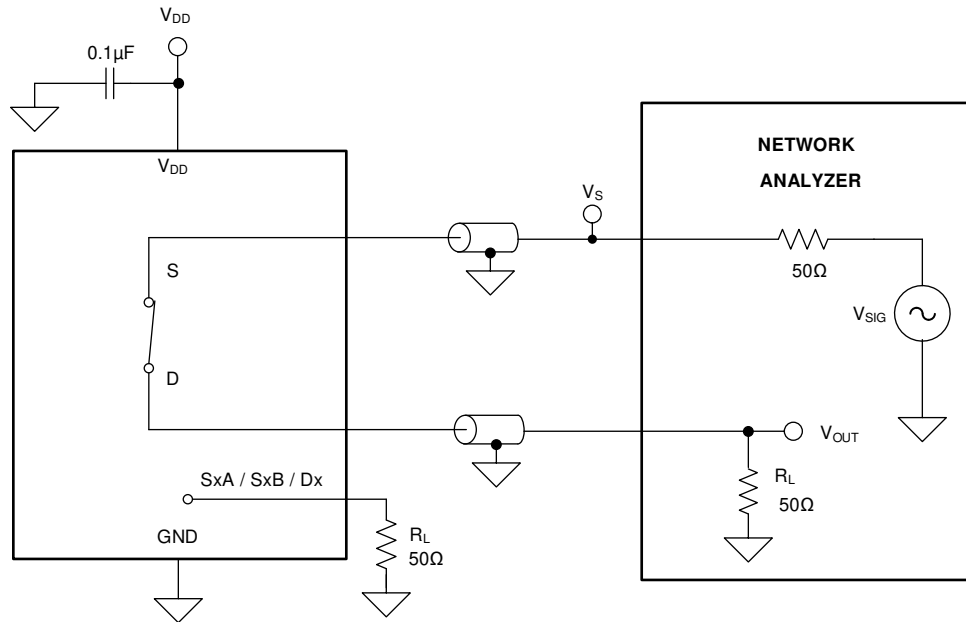


图 41. Bandwidth Measurement Setup

$$Attenuation = 20 \times \text{Log} \left( \frac{V_{OUT}}{V_S} \right)$$

(3)

## 8 Detailed Description

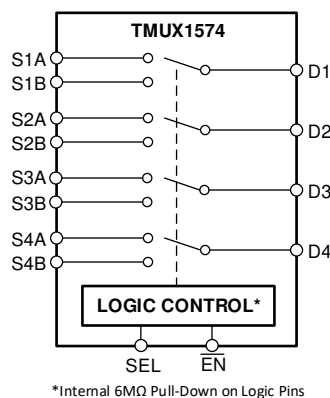
### 8.1 Overview

The TMUX1574 is a high speed 2:1 (SPDT) 4-ch. switch with powered-off protection up to 3.6 V. Wide operating supply of 1.5 V to 5.5 V allows for use in a wide array of applications from servers and communication equipment to industrial applications. The device supports bidirectional analog and digital signals on the source (SxA, SxB) and drain (Dx) pins. The wide bandwidth of this switch allows little or no attenuation of high-speed signals at the outputs to pass with minimum edge and phase distortion as well as propagation delay.

The enable ( $\overline{\text{EN}}$ ) pin is an active-low logic pin that controls the connection between the source (SxA, SxB) and drain (Dx) pins of the device. The select pin (SEL) controls the state of all four channels of the TMUX1574 and determines which source pin is connected to the drain. Fail-Safe Logic circuitry allows voltages on the logic control pins to be applied before the supply pin, protecting the device from potential damage. All logic control inputs have 1.8V logic compatible thresholds, ensuring both TTL and CMOS logic compatibility when operating in the valid supply voltage range.

Powered-off protection up to 3.6 V on the signal path of the TMUX1574 provides isolation when the supply voltage is removed ( $V_{\text{DD}} = 0 \text{ V}$ ). Without this protection feature, the system can back-power the supply rail through an internal ESD diode and cause potential damage to the system.

### 8.2 Functional Block Diagram



### 8.3 Feature Description

#### 8.3.1 Bidirectional Operation

The TMUX1574 conducts equally well from source (SxA, SxB) to drain (Dx) or from drain (Dx) to source (SxA, SxB). Each channel has very similar characteristics in both directions and supports both analog and digital signals.

#### 8.3.2 Beyond Supply Operation

When the TMUX1574 is powered from 1.5 V to 5.5 V, the valid signal path input/output voltage ranges from GND to  $V_{\text{DD}} \times 2$ , with a maximum input/output voltage of 5.5 V.

Example 1: If the TMUX1574 is powered at 1.5V, the signal range is 0 V to 3 V.

Example 2: If the TMUX1574 is powered at 3V, the signal range is 0 V to 5.5 V.

Example 3: If the TMUX1574 is powered at 5.5V, the signal range is 0 V to 5.5 V.

Other voltage levels not mentioned in the examples support Beyond Supply Operation as long as the supply voltage falls within the recommended operation conditions of 1.5 V to 5.5 V.

## Feature Description (接下页)

### 8.3.3 1.8 V Logic Compatible Inputs

The TMUX1574 has 1.8-V logic compatible control inputs. Regardless of the  $V_{DD}$  voltage, the control input thresholds remain fixed, allowing a 1.8-V processor GPIO to control the TMUX1574 without the need for an external translator. This saves both space and BOM cost. For more information on 1.8 V logic implementations, refer to [Simplifying Design with 1.8 V logic Muxes and Switches](#).

### 8.3.4 Powered-off Protection

Powered-off protection up to 3.6 V on the signal path of the TMUX1574 provides isolation when the supply voltage is removed ( $V_{DD} = 0$  V). When the TMUX1574 is powered-off, the I/Os of the device remain in a high-Z state. Powered-off protection minimizes system complexity by removing the need for power supply sequencing on the signal path. The device performance remains within the leakage performance mentioned in the Electrical Specifications. For more information on powered-off protection, refer to [Eliminate Power Sequencing with Powered-off Protection Signal Switches](#).

### 8.3.5 Fail-Safe Logic

The TMUX1574 has Fail-Safe Logic on the control input pins (SELx) which allows for operation up to 5.5 V, regardless of the state of the supply pin. This feature allows voltages on the control pins to be applied before the supply pin, protecting the device from potential damage. Fail-Safe Logic minimizes system complexity by removing the need for power supply sequencing on the logic control pins. For example, the Fail-Safe Logic feature allows the select pins of the TMUX1574 to be ramped to 5.5 V while  $V_{DD} = 0$  V. Additionally, the feature enables operation of the TMUX1574 with  $V_{DD} = 1.5$  V while allowing the select pins to interface with a logic level of another device up to 5.5 V.

### 8.3.6 Low Capacitance

The TMUX1574 has very low capacitance in both the ON and OFF states on the source and drain pins. Low capacitance helps to reduce large overshoots and ringing of an amplifier circuit when the switch is connected to the feedback network. Additionally, low capacitance improves system settling time by reducing the switch time constant formed by the On-resistance and On-capacitance. For more information on the benefits of low capacitance refer to [Improve Stability Issues with Low  \$C\_{ON}\$  Multiplexers](#).

### 8.3.7 Integrated Pull-Down Resistors

The TMUX1574 has internal weak pull-down resistors (6 M $\Omega$ ) to GND to ensure the logic pins are not left floating. This feature integrates up to four external components and reduces system size and cost.

## 8.4 Device Functional Modes

The enable ( $\overline{EN}$ ) pin is an active-low logic pin that controls the connection between the source (SxA, SxB) and drain (Dx) pins of the device. When the enable pin is pulled high, all switches are turned off. When the enable is pulled low, the select pin controls the signal path selection. The select pin (SEL) controls the state of all four channels of the TMUX1574 and determines which source pin is connected to the drain pins. When the select pin is pulled low, the SxA pin conducts to the corresponding Dx pins. When the select pin is pulled high, the SxB pin conducts to the corresponding Dx pins. The TMUX1574 logic pins have internal weak pull-down resistors (6 M $\Omega$ ) to GND so that it powers-on in a known state.

The TMUX1574 can be operated without any external components except for the supply decoupling capacitors. Unused logic control pins should be tied to GND or V<sub>DD</sub> in order to ensure the device does not consume additional current as highlighted in [Implications of Slow or Floating CMOS Inputs](#). Unused signal path inputs (SxA, SxB, or Dx) should be connected to GND.

## 8.5 Truth Tables

表 1. TMUX1574 Truth Table

INPUTS		Selected Source Pins Connected To Drain Pins (Dx)
$\overline{EN}$	SEL	
0	0	S1A connected to D1 S2A connected to D2 S3A connected to D3 S4A connected to D4
0	1	S1B connected to D1 S2B connected to D2 S3B connected to D3 S4B connected to D4
1	X <sup>(1)</sup>	Hi-Z (OFF)

(1) X denotes *don't care*.

## 9 Application and Implementation

### 注

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes. Customers should validate and test their design implementation to confirm system functionality.

### 9.1 Application Information

The TMUX15xx family offers high-speed system performance across a wide operating supply (1.5 V to 5.5 V) and operating temperature (-40°C to +125°C). The TMUX1574 supports a number of features that improve system performance such as [1.8 V logic compatibility](#), [supports input voltages beyond supply](#), [Fail-Safe Logic](#), and [Powered-off Protection up to 3.6 V](#). These features make the TMUX15xx a family of protection multiplexers and switches that can reduce system complexity, board size, and overall system cost.

### 9.2 Typical Application

Common applications that require the features of the TMUX1574 include multiplexing various protocols from a processor or MCU such as SPI, JTAG, or standard GPIO signals. The TMUX1574 provides superior isolation performance when the device is powered. The added benefit of powered-off protection allows a system to minimize complexity by eliminating the need for power sequencing in hot-swap and live insertion applications. The example shown in [图 42](#) illustrates the use of the TMUX1574 to multiplex an SPI bus to multiple flash memory devices.

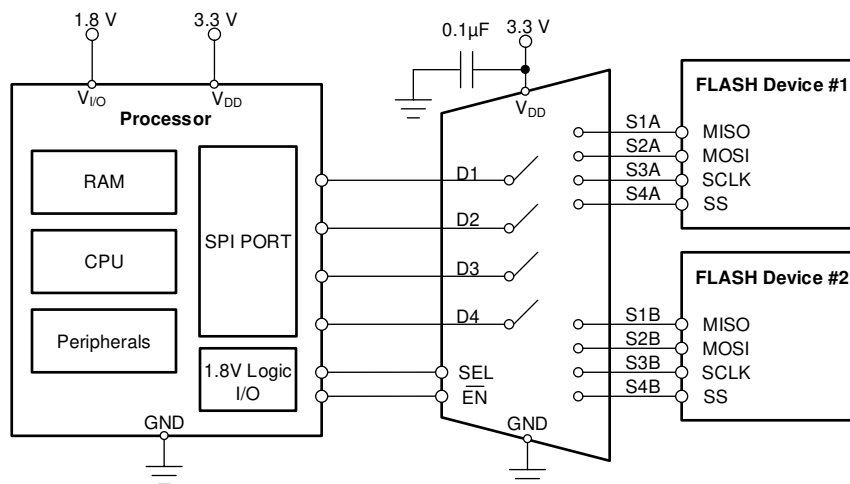


图 42. Multiplexing Flash Memory

#### 9.2.1 Design Requirements

For this design example, use the parameters listed in [表 2](#).

表 2. Design Parameters

PARAMETERS	VALUES
Supply ( $V_{DD}$ )	3.3 V
Input / Output signal range	0 V to 3.3 V
Control logic thresholds	1.8 V compatible

### 9.2.2 Detailed Design Procedure

The TMUX1574 can be operated without any external components except for the supply decoupling capacitors. The TMUX1574 has internal weak pull-down resistors (6 M $\Omega$ ) to GND so that it powers-on with the switches in a known state. All inputs signals passing through the switch must fall within the recommend operating conditions of the TMUX1574 including signal range and continuous current. For this design example, with a supply of 3.3 V, the signals can range from 0 V to 3.3 V when the device is powered. This example can also utilize the [Powered-off Protection](#) feature and the inputs can range from 0 V to 3.6 V when  $V_{DD} = 0$  V. The max continuous current can be 25 mA. Due to the voltage range and high speed capability, the TMUX1574 example is suitable for use in SPI, JTAG, and I2S applications. Refer to [Enabling SPI-based flash memory expansion by using multiplexers](#) for more information on using switches and multiplexers for SPI protocol expansion.

### 9.2.3 Application Curves

Two important specifications when using a switch or multiplexer to pass signals are the device propagation delay and skew.

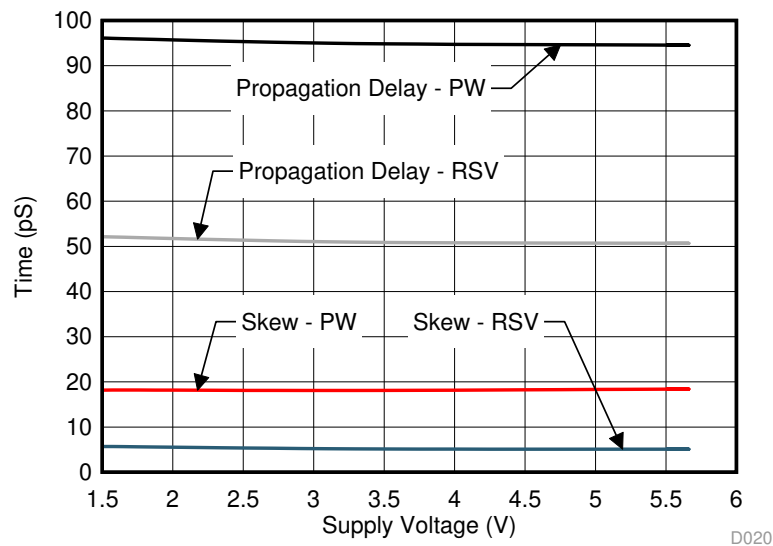


图 43. Propagation Delay and Skew Measurement

## 10 Power Supply Recommendations

The TMUX1574 operates across a wide supply range of 1.5 V to 5.5 V. Do not exceed the absolute maximum ratings because stresses beyond the listed ratings can cause permanent damage to the devices.

Power-supply bypassing improves noise margin and prevents switching noise propagation from the  $V_{DD}$  supply to other components. Good power-supply decoupling is important to achieve optimum performance. For improved supply noise immunity, use a supply decoupling capacitor ranging from 0.1  $\mu$ F to 10  $\mu$ F from  $V_{DD}$  to ground. Place the bypass capacitors as close to the power supply pins of the device as possible using low-impedance connections. TI recommends using multi-layer ceramic chip capacitors (MLCCs) that offer low equivalent series resistance (ESR) and inductance (ESL) characteristics for power-supply decoupling purposes. For very sensitive systems, or for systems in harsh noise environments, avoiding the use of vias for connecting the capacitors to the device pins may offer superior noise immunity. The use of multiple vias in parallel lowers the overall inductance and is beneficial for connections to ground planes.

## 11 Layout

### 11.1 Layout Guidelines

When a PCB trace turns a corner at a 90° angle, a reflection can occur. A reflection occurs primarily because of the change of width of the trace. At the apex of the turn, the trace width increases to 1.414 times the width. This increase upsets the transmission-line characteristics, especially the distributed capacitance and self-inductance of the trace which results in the reflection. Not all PCB traces can be straight and therefore some traces must turn corners. [图 44](#) shows progressively better techniques of rounding corners. Only the last example (BEST) maintains constant trace width and minimizes reflections.

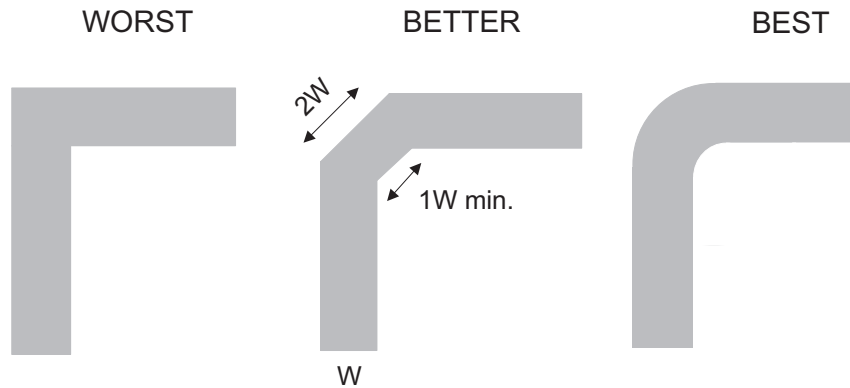


图 44. Trace Example

Route the high-speed signals using a minimum of vias and corners which reduces signal reflections and impedance changes. When a via must be used, increase the clearance size around it to minimize its capacitance. Each via introduces discontinuities in the signal's transmission line and increases the chance of picking up interference from the other layers of the board. Be careful when designing test points, through-hole pins are not recommended at high frequencies.

Do not route high speed signal traces under or near crystals, oscillators, clock signal generators, switching regulators, mounting holes, magnetic devices or ICs that use or duplicate clock signals.

Avoid stubs on the high-speed signals traces because they cause signal reflections.

Route all high-speed signal traces over continuous GND planes, with no interruptions.

Avoid crossing over anti-etch, commonly found with plane splits.

When working with high frequencies, a printed circuit board with at least four layers is recommended; two signal layers separated by a ground and power layer as shown in [图 45](#).

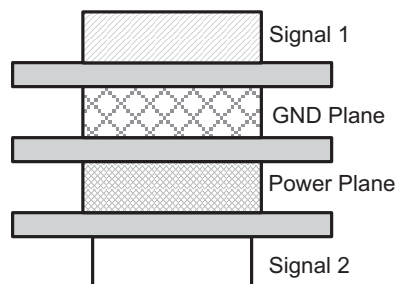


图 45. Example Layout

The majority of signal traces must run on a single layer, preferably Signal 1. Immediately next to this layer must be the GND plane, which is solid with no cuts. Avoid running signal traces across a split in the ground or power plane. When running across split planes is unavoidable, sufficient decoupling must be used. Minimizing the number of signal vias reduces EMI by reducing inductance at high frequencies.

[图 46](#) illustrates an example of a PCB layout with the TMUX1574. Some key considerations are:

## Layout Guidelines (接下页)

Decouple the  $V_{DD}$  pin with a 0.1- $\mu\text{F}$  capacitor, placed as close to the pin as possible. Make sure that the capacitor voltage rating is sufficient for the  $V_{DD}$  supply.

High-speed switches require proper layout and design procedures for optimum performance.

Keep the input lines as short as possible.

Use a solid ground plane to help reduce electromagnetic interference (EMI) noise pickup.

Do not run sensitive analog traces in parallel with digital traces. Avoid crossing digital and analog traces if possible, and only make perpendicular crossings when necessary.

## 11.2 Layout Example

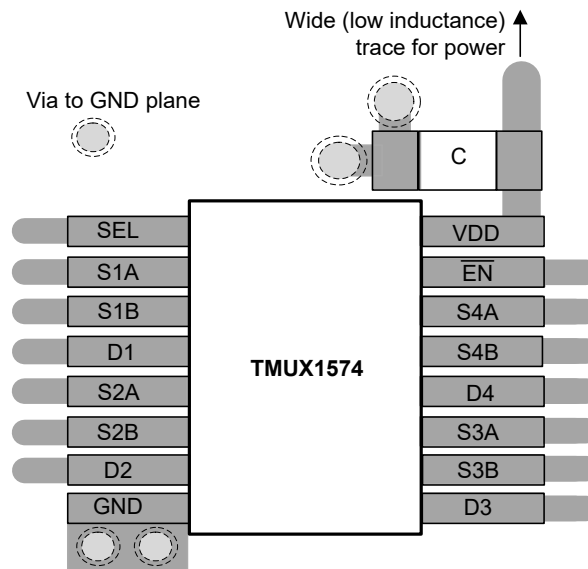


图 46. Example Layout

## 12 器件和文档支持

### 12.1 文档支持

#### 12.1.1 相关文档

- 德州仪器 (TI), 《[使用低 CON 多路复用器改善稳定性问题](#)》。
- 德州仪器 (TI), 《[通过使用多路复用器实现基于 SPI 的闪存扩展](#)》。
- 德州仪器 (TI), 《[使用 1.8V 逻辑多路复用器和开关简化设计](#)》。
- 德州仪器 (TI), 《[利用关断保护信号开关消除电源排序](#)》。
- 德州仪器 (TI), 《[高电压模拟多路复用器的系统级保护](#)》。
- 德州仪器 (TI), 《[高速接口布局指南](#)》。
- 德州仪器 (TI), 《[高速布局指南](#)》。
- 德州仪器 (TI), 《[QFN/SON PCB 连接](#)》。
- 德州仪器 (TI), 《[四方扁平封装无引线逻辑封装](#)》。

### 12.2 接收文档更新通知

要接收文档更新通知, 请导航至 [TI.com.cn](http://TI.com.cn) 上的器件产品文件夹。单击右上角的 [通知我](#) 进行注册, 即可每周接收产品信息更改摘要。有关更改的详细信息, 请查看任何已修订文档中包含的修订历史记录。

### 12.3 社区资源

[TI E2E™ support forums](#) are an engineer's go-to source for fast, verified answers and design help — straight from the experts. Search existing answers or ask your own question to get the quick design help you need.

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### 12.4 商标

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### 12.5 静电放电警告



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ESD 的损坏小至导致微小的性能降级, 大至整个器件故障。精密的集成电路可能更容易受到损坏, 这是因为非常细微的参数更改都可能会导致器件与其发布的规格不相符。

### 12.6 Glossary

[SLYZ022](#) — *TI Glossary*.

This glossary lists and explains terms, acronyms, and definitions.

### 13 机械、封装和可订购信息

以下页面包含机械、封装和可订购信息。这些信息是指定器件的最新可用数据。数据如有变更，恕不另行通知，且不会对此文档进行修订。如需获取此数据表的浏览器版本，请查阅左侧的导航栏。

**PACKAGING INFORMATION**

Orderable part number	Status (1)	Material type (2)	Package   Pins	Package qty   Carrier	RoHS (3)	Lead finish/ Ball material (4)	MSL rating/ Peak reflow (5)	Op temp (°C)	Part marking (6)
<a href="#">TMUX1574DYR</a>	Active	Production	SOT-23-THIN (DYY)   16	3000   LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	TMUX1574
TMUX1574DYR.A	Active	Production	SOT-23-THIN (DYY)   16	3000   LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	TMUX1574
TMUX1574DYR.G4	Active	Production	SOT-23-THIN (DYY)   16	3000   LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	TMUX1574
TMUX1574DYR.G4.A	Active	Production	SOT-23-THIN (DYY)   16	3000   LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	TMUX1574
<a href="#">TMUX1574PWR</a>	Active	Production	TSSOP (PW)   16	2000   LARGE T&R	Yes	NIPDAU   SN	Level-1-260C-UNLIM	-40 to 125	MUX1574
TMUX1574PWR.A	Active	Production	TSSOP (PW)   16	2000   LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	MUX1574
TMUX1574PWR.G4	Active	Production	TSSOP (PW)   16	2000   LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	MUX1574
TMUX1574PWR.G4.A	Active	Production	TSSOP (PW)   16	2000   LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	MUX1574
<a href="#">TMUX1574RSVR</a>	Active	Production	UQFN (RSV)   16	3000   LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	1574
TMUX1574RSVR.A	Active	Production	UQFN (RSV)   16	3000   LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	1574
TMUX1574RSVR.G4.A	Active	Production	UQFN (RSV)   16	3000   LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	1574
TMUX1574T8RSVR	Active	Production	UQFN (RSV)   16	3000   LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	1574
TMUX1574T8RSVR.A	Active	Production	UQFN (RSV)   16	3000   LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	1574

(1) **Status:** For more details on status, see our [product life cycle](#).

(2) **Material type:** When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

(3) **RoHS values:** Yes, No, RoHS Exempt. See the [TI RoHS Statement](#) for additional information and value definition.

(4) **Lead finish/Ball material:** Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

(5) **MSL rating/Peak reflow:** The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

**(6) Part marking:** There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "-" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

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**TAPE AND REEL INFORMATION**

**QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE**


\*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
TMUX1574DYYR	SOT-23-THIN	DYY	16	3000	330.0	12.4	4.8	3.6	1.6	8.0	12.0	Q3
TMUX1574DYYRG4	SOT-23-THIN	DYY	16	3000	330.0	12.4	4.8	3.6	1.6	8.0	12.0	Q3
TMUX1574PWR	TSSOP	PW	16	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1
TMUX1574PWRG4	TSSOP	PW	16	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1
TMUX1574RSVR	UQFN	RSV	16	3000	178.0	13.5	2.1	2.9	0.75	4.0	12.0	Q1
TMUX1574T8RSVR	UQFN	RSV	16	3000	180.0	9.5	2.1	2.9	0.75	4.0	8.0	Q1

**TAPE AND REEL BOX DIMENSIONS**


\*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
TMUX1574DYYR	SOT-23-THIN	DYY	16	3000	336.6	336.6	31.8
TMUX1574DYYRG4	SOT-23-THIN	DYY	16	3000	336.6	336.6	31.8
TMUX1574PWR	TSSOP	PW	16	2000	353.0	353.0	32.0
TMUX1574PWRG4	TSSOP	PW	16	2000	353.0	353.0	32.0
TMUX1574RSVR	UQFN	RSV	16	3000	189.0	185.0	36.0
TMUX1574T8RSVR	UQFN	RSV	16	3000	189.0	185.0	36.0

## GENERIC PACKAGE VIEW

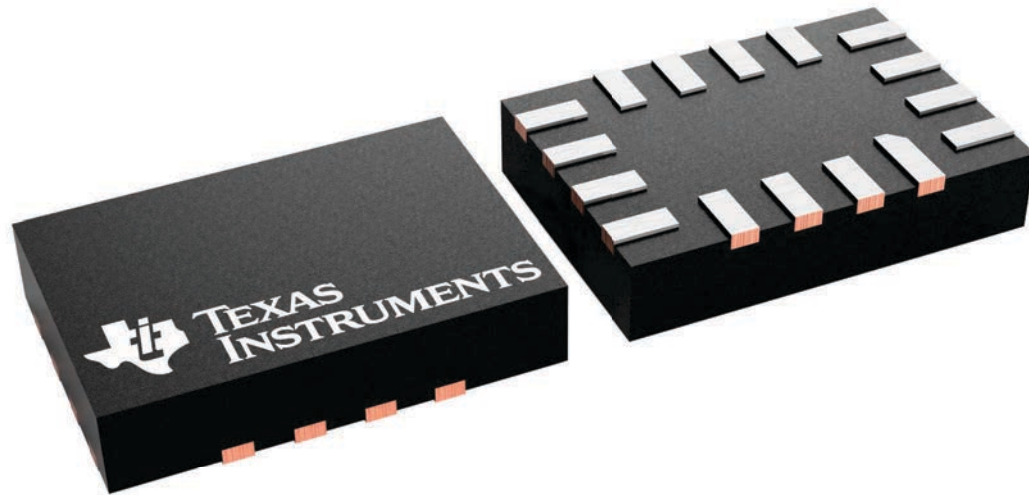
**RSV 16**

**UQFN - 0.55 mm max height**

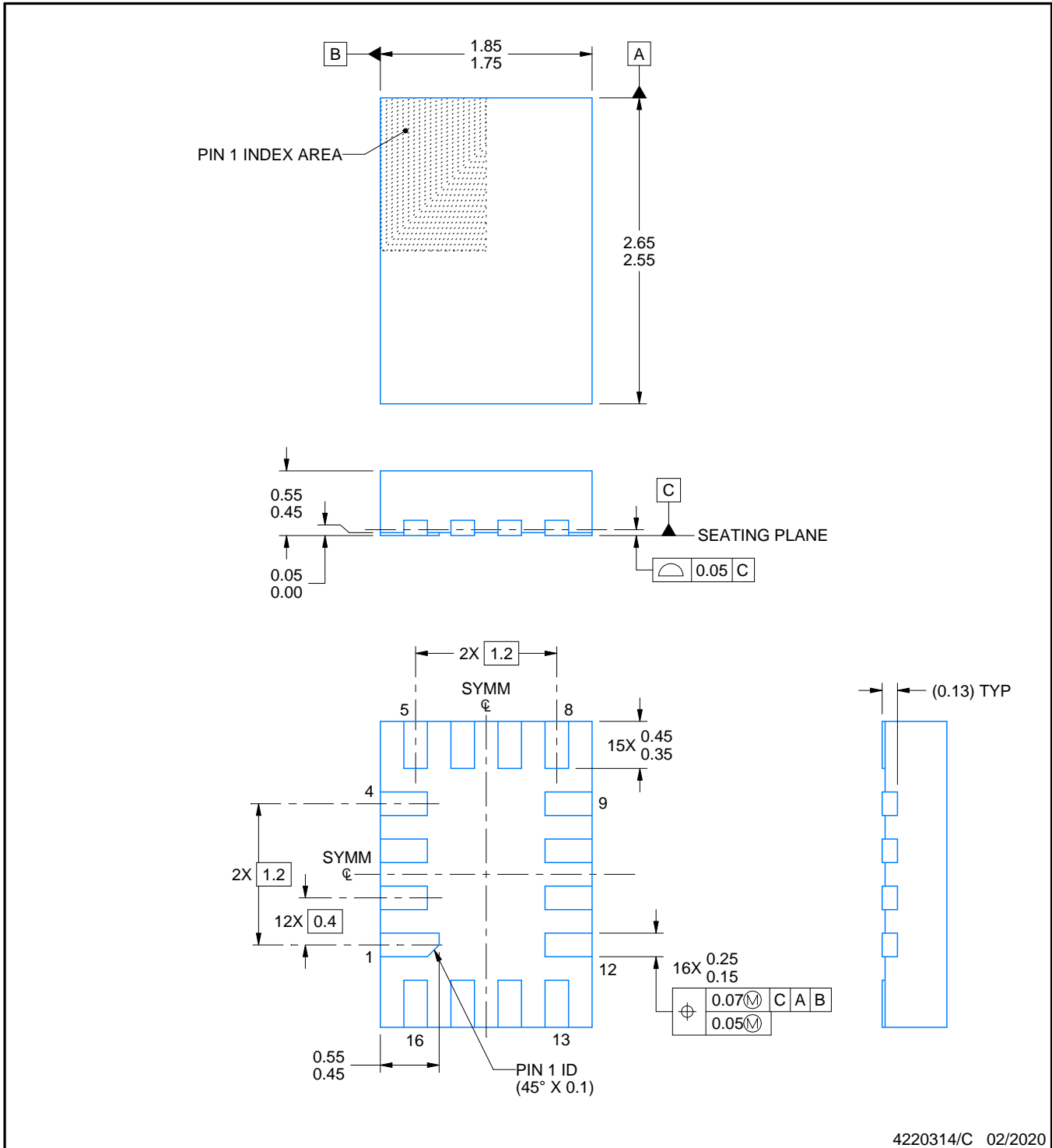
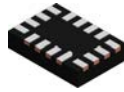
1.8 x 2.6, 0.4 mm pitch

ULTRA THIN QUAD FLATPACK - NO LEAD

This image is a representation of the package family, actual package may vary.  
Refer to the product data sheet for package details.



4231225/A



4220314/C 02/2020

NOTES:

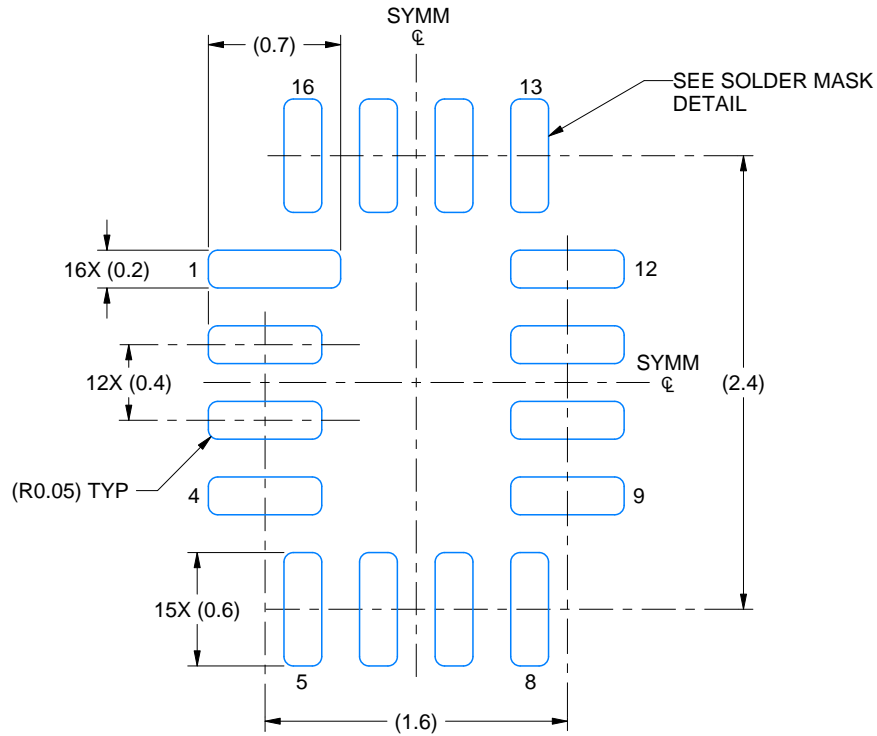
1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.

# EXAMPLE BOARD LAYOUT

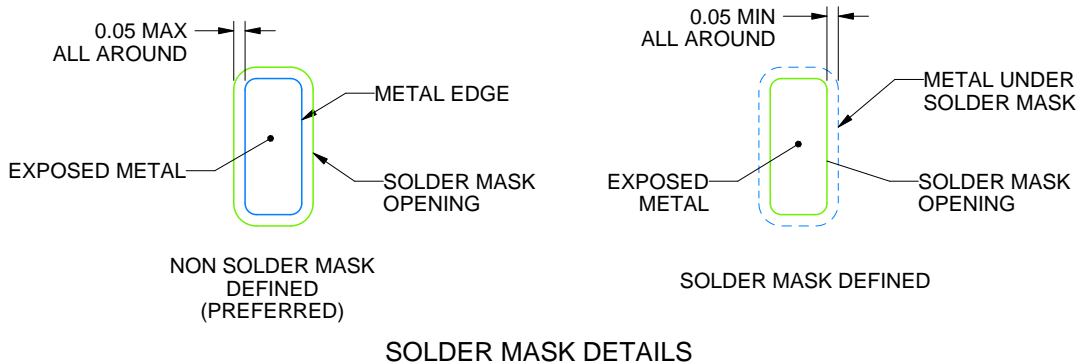
RSV0016A

UQFN - 0.55 mm max height

ULTRA THIN QUAD FLATPACK - NO LEAD



LAND PATTERN EXAMPLE  
EXPOSED METAL SHOWN  
SCALE: 25X



4220314/C 02/2020

NOTES: (continued)

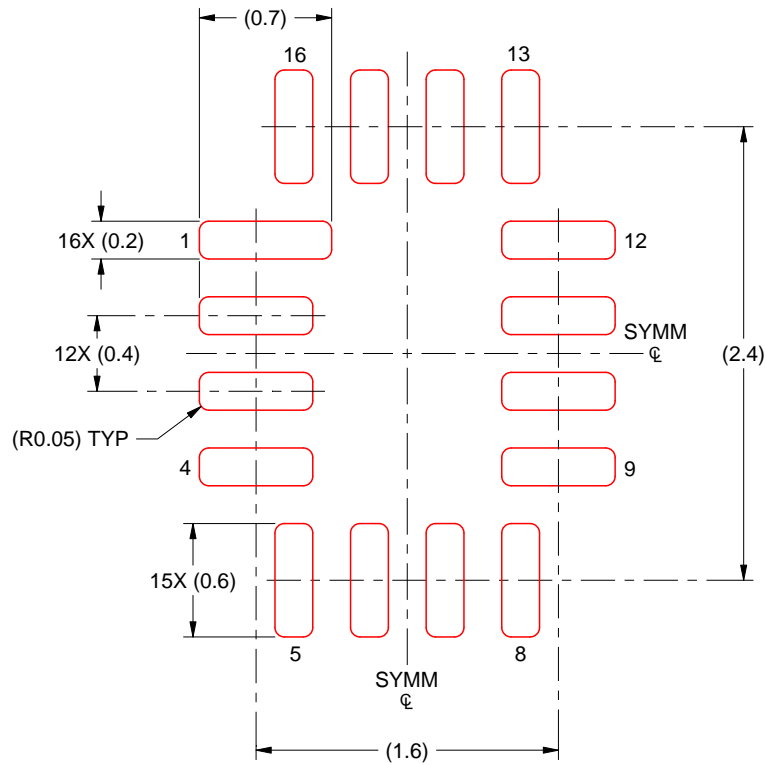
3. For more information, see Texas Instruments literature number SLUA271 ([www.ti.com/lit/slua271](http://www.ti.com/lit/slua271)).

# EXAMPLE STENCIL DESIGN

RSV0016A

UQFN - 0.55 mm max height

ULTRA THIN QUAD FLATPACK - NO LEAD

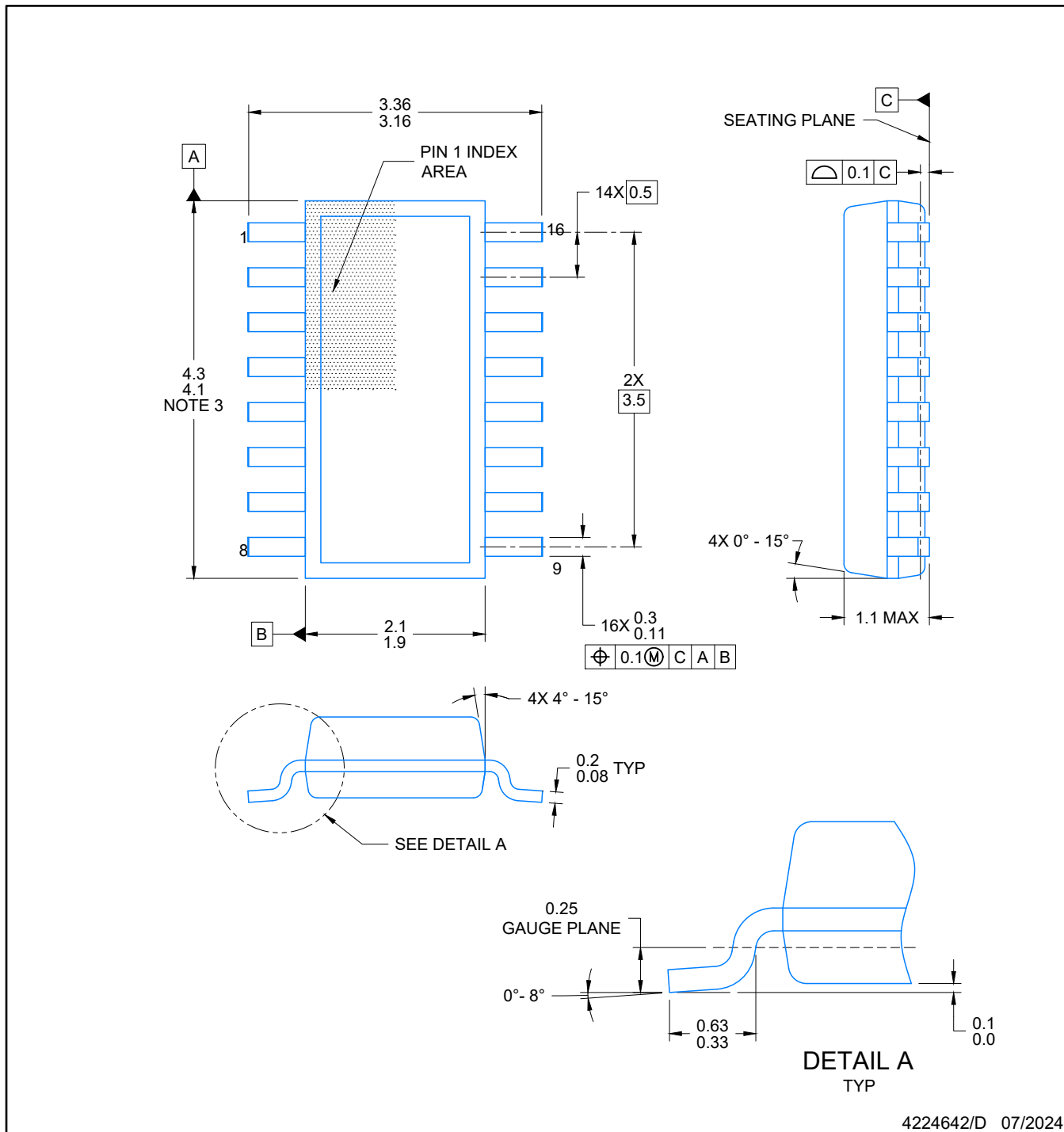


SOLDER PASTE EXAMPLE  
BASED ON 0.125 MM THICK STENCIL  
SCALE: 25X

4220314/C 02/2020

NOTES: (continued)

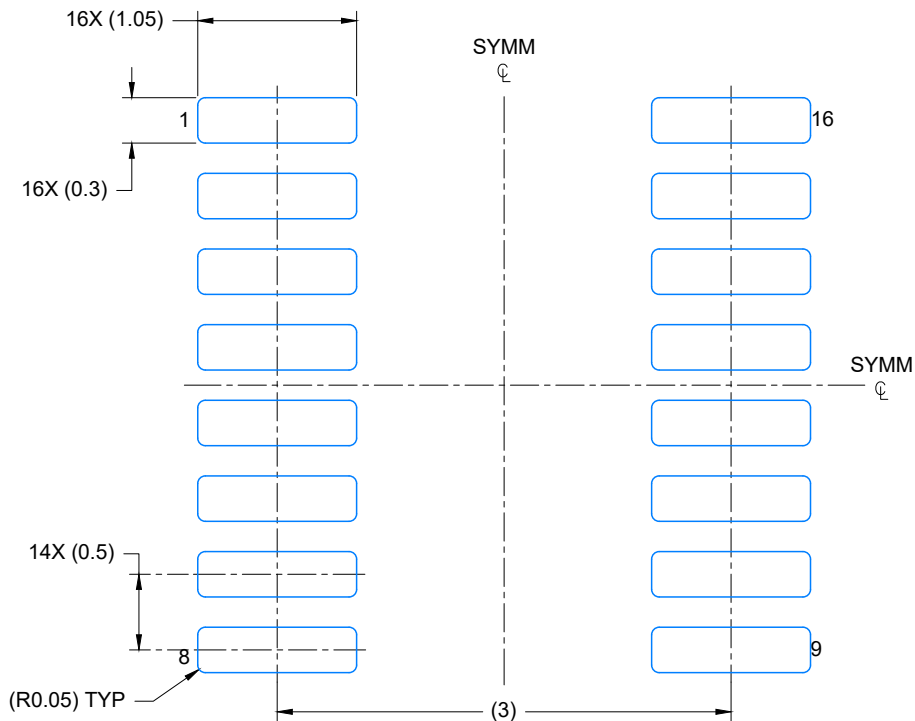
4. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.



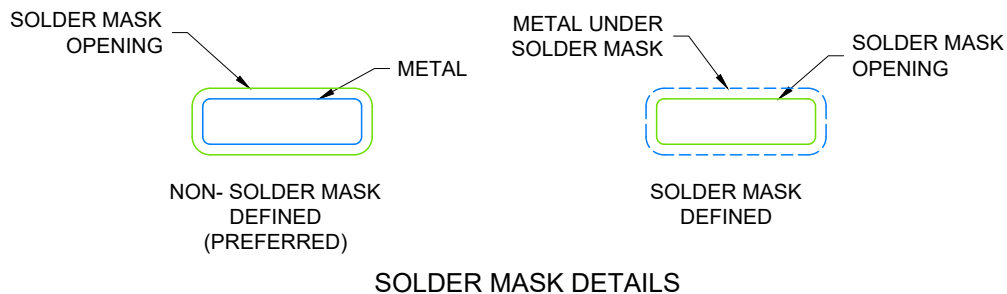
4224642/D 07/2024

NOTES:

1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.15 per side.
4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.50 per side.
5. Reference JEDEC Registration MO-345, Variation AA



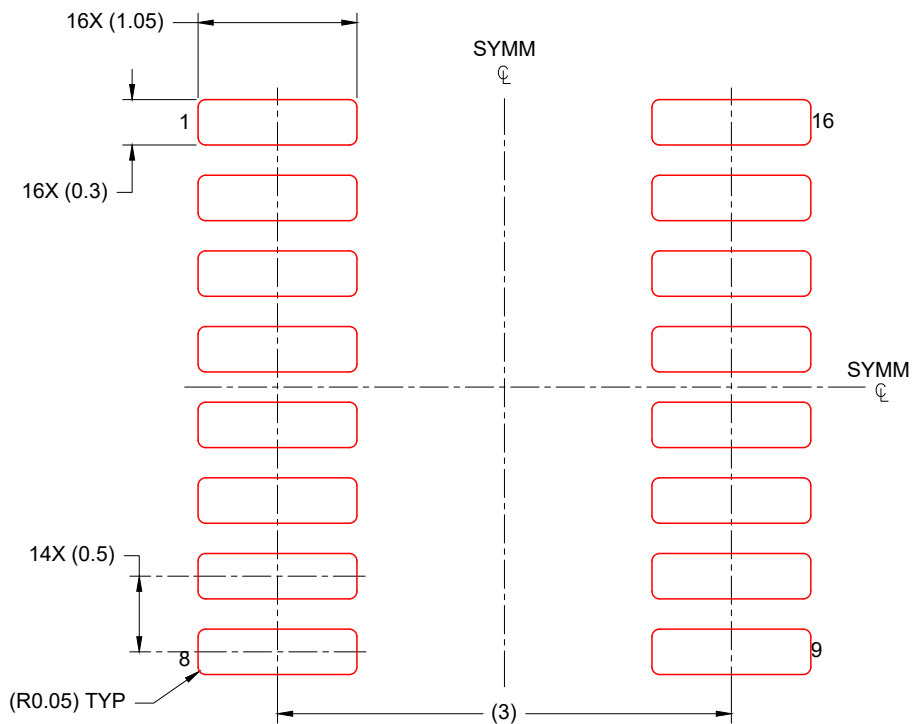
LAND PATTERN EXAMPLE  
EXPOSED METAL SHOWN  
SCALE: 20X



4224642/D 07/2024

NOTES: (continued)

- 6. Publication IPC-7351 may have alternate designs.
- 7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.

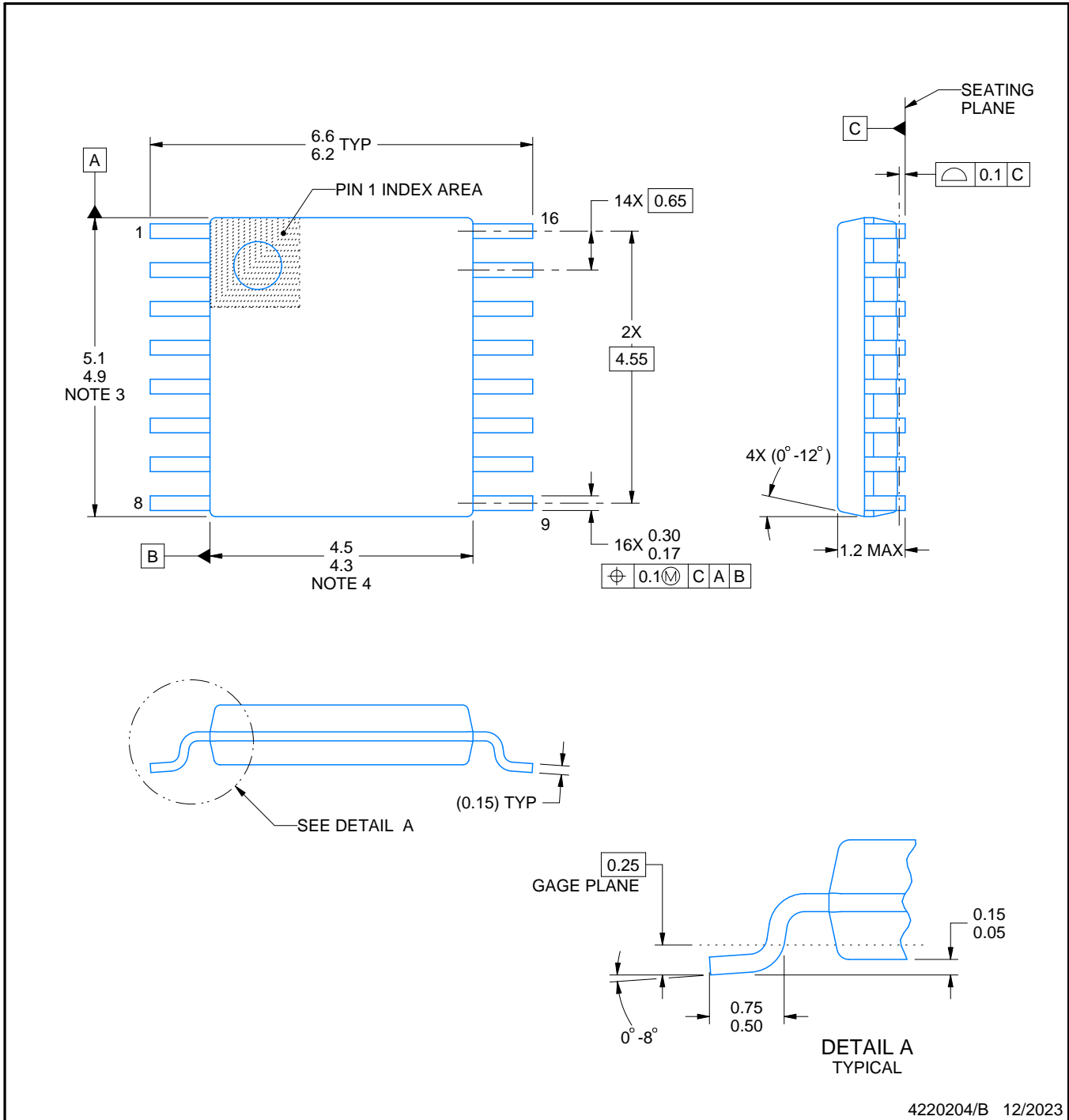
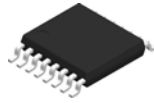


SOLDER PASTE EXAMPLE  
BASED ON 0.125 mm THICK STENCIL  
SCALE: 20X

4224642/D 07/2024

NOTES: (continued)

- 8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 9. Board assembly site may have different recommendations for stencil design.



4220204/B 12/2023

NOTES:

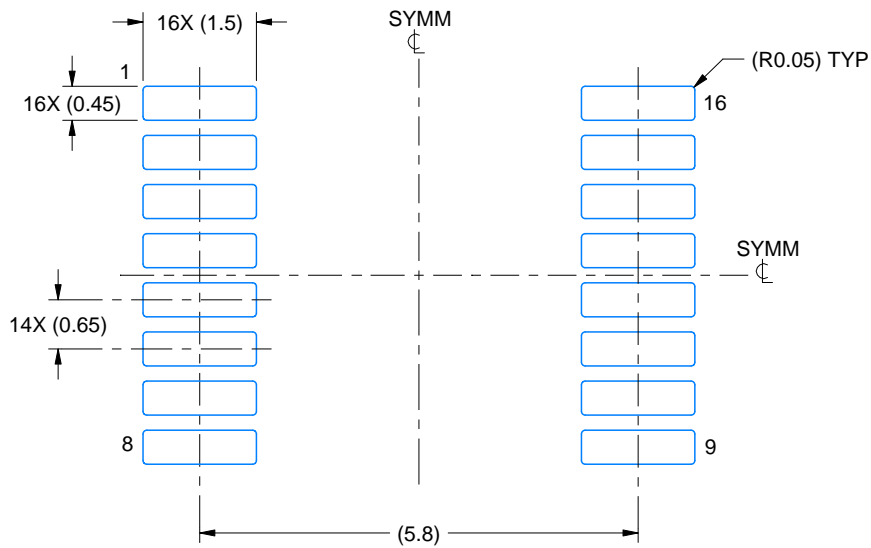
1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.15 mm per side.
4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
5. Reference JEDEC registration MO-153.

# EXAMPLE BOARD LAYOUT

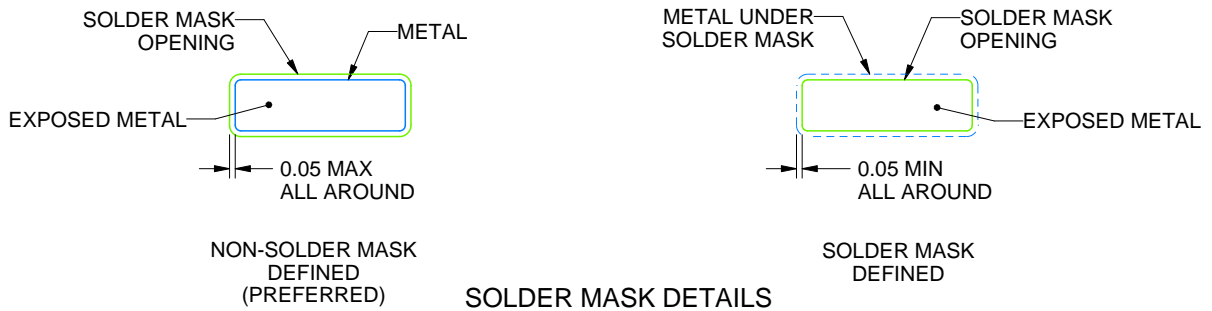
PW0016A

TSSOP - 1.2 mm max height

SMALL OUTLINE PACKAGE



LAND PATTERN EXAMPLE  
EXPOSED METAL SHOWN  
SCALE: 10X



SOLDER MASK DETAILS

4220204/B 12/2023

NOTES: (continued)

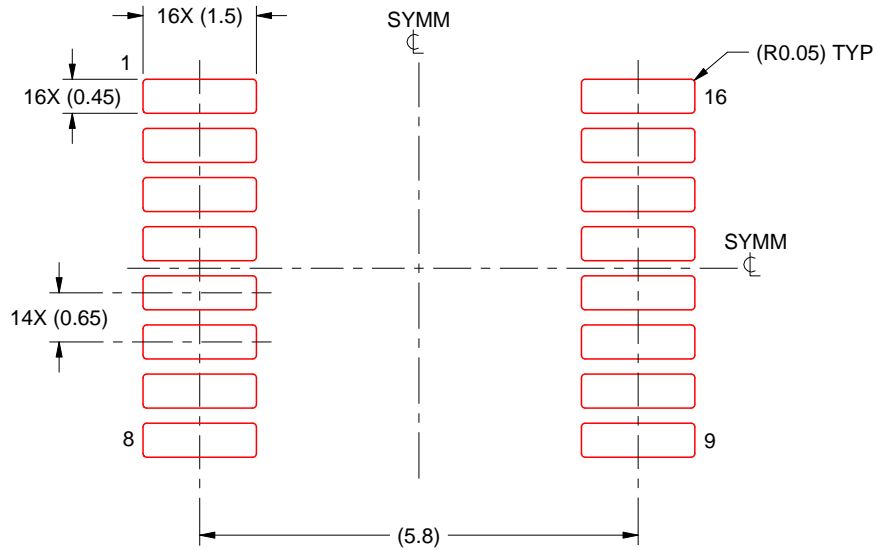
- 6. Publication IPC-7351 may have alternate designs.
- 7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.

# EXAMPLE STENCIL DESIGN

PW0016A

TSSOP - 1.2 mm max height

SMALL OUTLINE PACKAGE



SOLDER PASTE EXAMPLE  
BASED ON 0.125 mm THICK STENCIL  
SCALE: 10X

4220204/B 12/2023

NOTES: (continued)

8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
9. Board assembly site may have different recommendations for stencil design.

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最后更新日期：2025 年 10 月